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### => DISPLAY HISTORY FULL L1-

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FILE 'HCAPLUS' ENTERED AT 16:16:27 ON 10 FEB 2009
          170 SEA IHARA E?/AU
L1
L2
          1262 SEA YANAGISAWA T?/AU
             1 SEA L1 AND L2
L3
FILE 'REGISTRY' ENTERED AT 16:17:07 ON 10 FEB 2009
             1 SEA 10043-11-5
L4
              E BORON NITRIDE/CN
             1 SEA "BORON NITRIDE"/CN
L5
           384 SEA (B (L) N)/ELS (L) 2/ELC.SUB
L6
    FILE 'HCA' ENTERED AT 16:24:24 ON 10 FEB 2009
          3849 SEA (L4 OR L5 OR L6) (L) (CUBE# OR CUBIC?)
L7
L8
          7735 SEA CBN OR (C OR CUBE# OR CUBIC) (2A) (BN OR (BORON# OR
               B) (A) NITRIDE#)
          1141 SEA (L4 OR L5 OR L6) (L) HEXAG?
L9
          4044 SEA HBN OR (H OR HEXAG?) (2A) (BN OR (BORON# OR B) (A) NITRID
L10
               E#)
         1200 SEA (L4 OR L5 OR L6) AND (CUBE# OR CUBIC?) AND HEXAG?
L11
L12 11160 SEA (MAGNESIUM# OR MG)(2A)(DOPANT? OR DOPE# OR DOPING#
               OR INTERSPERS? OR INTERCALAT? OR ADMIX? OR INMIX? OR
               INTERMIX? OR COMMIX? OR IMMIX?)
     FILE 'REGISTRY' ENTERED AT 16:28:17 ON 10 FEB 2009
               E MG/ELS
       164846 SEA MG/ELS
L13
     FILE 'HCA' ENTERED AT 16:29:05 ON 10 FEB 2009
         12834 SEA L13 (L) (DOPE# OR DOPING# OR DOPANT?)
L14
     FILE 'REGISTRY' ENTERED AT 16:31:22 ON 10 FEB 2009
               E LI/ELS
L15
       124453 SEA LI/ELS
    FILE 'HCA' ENTERED AT 16:34:56 ON 10 FEB 2009
L16
     383325 SEA L15
               QUE CAT# OR CATALY?
L17
          1395 SEA (L7 OR L8) AND (L9 OR L10)
L18
        1567 SEA L18 OR L11
L19
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## LANGEL 10/568,438

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275829 SEA (PHASE# OR PHASIC? OR PHASING#) (3A) (TRANSITION? OR
L20
                 TRANSFORM? OR CHANG? OR VARY? OR VARIES OR VARIED OR
                 VARIAB? OR ALTER OR ALTERS OR ALTERED OR ALTERED OR
                 ALTERRING# OR ALTERING# OR ALTERAT?)
L21
            219 SEA L19 AND L20
             47 SEA L21 AND L17
L22
              4 SEA L22 AND (L12 OR L14)
·L23
L24
              14 SEA L22 AND L16
L25
         857410 SEA L13
             23 SEA L22 AND L25
L26
L27
                OUE DOPE# OR DOPING# OR DOPANT?
L28
             4 SEA L26 AND L27
L29
             3 SEA L24 AND L27
             9 SEA L19 AND ((L25 AND L27) OR L12)
L30
           9 SEA L19 AND ((L25 AND L27) OR L
152 SEA L19 AND (L25 OR L12)
L31
             52 SEA L31 AND L16
L32
L33
             4 SEA L32 AND L27
L34
             13 SEA L32 AND L20
              QUE PHASE# OR PHASIC? OR PHASING#
L35
           QUE PHASE# OR PI
745 SEA L19 AND L35
L36
L37
            7 SEA L19 AND (L12 OR L14)
             70 SEA L36 AND (L12 OR L25) .
L38
          8 SEA L38 AND L2,
20 SEA L38 AND L16
38 SEA L38 AND L17
37 SEA L38 AND L20
10 SEA L40 AND L41
13 SEA L40 AND L42
23 SEA L41 AND L42
L39
L40
L41
L42
L43
L44
L45
L46
           27041 SEA L4 OR L5 OR L6
     FILE 'REGISTRY' ENTERED AT 16:59:56 ON 10 FEB 2009
                E MAGNESIUM NITRIDE/CN
L47
               2 SEA "MAGNESIUM NITRIDE"/CN
              34 SEA (MG (L) N)/ELS (L) 2/ELC.SUB
                E LITHIUM NITRIDE/CN
L49
              1 SEA "LITHIUM NITRIDE"/CN
              40 SEA (LI (L) N)/ELS (L) 2/ELC.SUB
L50
     FILE 'HCA' ENTERED AT 17:01:52 ON 10 FEB 2009
            987 SEA L47 OR L48 OR MG3N2
L51
            1723 SEA L49 OR L50 OR LI3N
L52
            61 SEA L19 AND L51
L53
L54
             81 SEA L19 AND L52
         21 SEA L53 AND L54
21 SEA L55 AND (L17 OR L27 OR L35)
41 SEA L53 AND L17
3 SEA L53 AND L27
L55
L56
L56
L57
L58
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37 SEA L53 AND L35
L59
L60
            .24 SEA L57 AND L59
             21 SEA (L57 OR L59) AND L54
L61
              9 SEA L23 OR L28 OR L29 OR L30 OR L33 OR L37 OR L39 OR L58
L62
             17 SEA (L24 OR L34 OR L43 OR L44) NOT L62
L63
            .34 SEA (L26 OR L45 OR L55 OR L56 OR L60 OR L61) NOT (L62 OR
L64
                L63)
              9 SEA 1808-2003/PY, PRY, AY AND L62
L65
             15 SEA 1808-2003/PY, PRY, AY AND L63
L66
             30 SEA 1808-2003/PY, PRY, AY AND L64
L67
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=> FILE HCA

FILE 'HCA' ENTERED AT 18:11:30 ON 10 FEB 2009

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### => D L65 1-9 CBIB ABS HITSTR HITIND RE

AB Cubic boron nitride is produced by holding hexagonal BN in presence of a catalyst substance under conditions in which cBN remains thermodynamically stable, to cause hBN to undergo a phase transition to form cBN. The catalyst contains a lithium source (such as Li3N), a magnesium source (such as magnesium nitride), and a carbon source (such as graphite). The performance of cBN is improved even though phase transition ratio from

```
hBN to cBN is increased.
IT
     10043-11-5, Boron nitride, processes
        (cubic-, abrasives ceramics; prodn. of lithium-,
        magnesium- and/or carbon-doped cubic
        BN ceramics for grinding wheels)
     10043-11-5 HCA
RN
     Boron nitride (BN) (CA INDEX NAME)
CN
B \equiv N
     7439-93-2, Lithium, uses 7439-95-4,
IT
     Magnesium, uses
        (dopant; prodn. of lithium-, magnesium- and/or carbon-
        doped cubic BN ceramics for grinding
        wheels)
     7439-93-2 HCA
RN
     Lithium (CA INDEX NAME)
CN
Li
RN
     7439-95-4 HCA
CN
     Magnesium (CA INDEX NAME)
Mg
     26134-62-3, Lithium nitride
IT
        (lithium source; prodn. of lithium-, magnesium- and/or carbon-
        doped cubic BN ceramics for grinding
        wheels)
     26134-62-3 HCA
RN
CN
     Lithium nitride (Li3N) (CA INDEX NAME)
   Li
Li-N-Li
IT
     12057-71-5, Magnesium nitride
        (magnesium source; prodn. of lithium-, magnesium- and/or carbon-
        doped cubic BN ceramics for grinding
        wheels)
     12057-71-5 HCA
RN
    Magnesium nitride (Mg3N2) (CA INDEX NAME)
CN
*** STRUCTURE DIAGRAM IS NOT AVAILABLE ***
     ICM C09K003-14
IC
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ICS C01B021-064; C04B035-5831; B24D005-06
     57-7 (Ceramics)
CC
     lithium magnesium carbon dopant boron nitride
ST
     ceramic grinding wheel
     Ceramics
IT
        (boron nitride; prodn. of lithium-, magnesium- and/or carbon-
        doped cubic BN ceramics for grinding
        wheels)
     Carbon black, processes
IT
     Hydrocarbons, processes
        (carbon source; prodn. of lithium-, magnesium- and/or carbon-
        doped cubic BN ceramics for grinding
        wheels)
IT
     Catalysts
        (lithium magnesium carbon-based; prodn. of lithium-, magnesium-
        and/or carbon-doped cubic BN
        ceramics for grinding wheels)
     Grinding wheels
ΙT
        (prodn. of lithium-, magnesium- and/or carbon-doped
        cubic BN ceramics for grinding wheels)
     7782-42-5, Graphite, processes
IT
        (carbon source; prodn. of lithium-, magnesium- and/or carbon-
        doped cubic BN ceramics for grinding
        wheels)
IT
     10043-11-5, Boron nitride, processes
        (cubic-, abrasives ceramics; prodn. of lithium-,
        magnesium- and/or carbon-doped cubic
        BN ceramics for grinding wheels)
     7439-93-2, Lithium, uses 7439-95-4,
IT
     Magnesium, uses
                      7440-44-0, Carbon, uses
        (dopant; prodn. of lithium-, magnesium- and/or carbon-
        doped cubic BN ceramics for grinding
        wheels)
IT
     26134-62-3, Lithium nitride
        (lithium source; prodn. of lithium-, magnesium- and/or carbon-
        doped cubic BN ceramics for grinding
        wheels)
IT
     12057-71-5, Magnesium nitride
        (magnesium source; prodn. of lithium-, magnesium- and/or carbon-
        doped cubic BN ceramics for grinding
        wheels)
RE
(1) Anon; EP 0407946 A1 HCA
(2) Anon; WO 2004069399 A1 HCA
(3) Anon; US 5332629 A HCA
L65 ANSWER 2 OF 9 HCA COPYRIGHT 2009 ACS on STN
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133:353863 Investigation of the processes of crystallization and

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ΙT

RN

CN

RN CN

ΙT

RN

CN

CC

 $B \equiv N$ 

57-2 (Ceramics)

```
sintering of cubic boron nitride and its physical
     properties. Shipilo, V. B.; Gameza, L. M.; Anichenko, N. G.;
     Gielisse, P. J. (Institute of Solid State and Semiconductor Physics,
     National Academy of Sciences of Belarus, Minsk, 220726, Belarus).
     Journal of Wide Bandgap Materials, 7(3), 213-260 (English)
                            ISSN: 1524-511X. Publisher:
     2000. CODEN: JWBMFT.
     Technomic Publishing Co., Inc..
     The equipment and technol. required for the successful synthesis of
     cubic boron nitride, i.e., as a com. valuable commodity with
     proven market acceptance, is detailed. A parametric study involving
     the kinetics of nucleation and crystal growth at different pressures
     and temps. formed the background for the presentation of the salient
     features of the crystn. processes involving various catalyst
    -solvent-dopant systems. The conditions necessary for
     producing sintered cBN based polycryst. compacts and composites have
     been presented. The results reported herein have important
     implications for future applications of cBN as an engineering
     material.
     12007-25-9, Magnesium diboride 26134-62-3, Lithium
     nitride li3n
        (catalyst-solvent; crystn. and sintering of
        cubic boron nitride in catalyst-solvent-
        dopant systems and phys. properties)
     12007-25-9 HCA
     Magnesium boride (MgB2) (CA INDEX NAME)
B \equiv Mq \equiv B
     26134-62-3 HCA
    Lithium nitride (Li3N) (CA INDEX NAME)
   Li
Li-N-Li
     10043-11-5, Boron nitride, processes
        (cubic, ceramics; crystn. and sintering of
       cubic boron nitride in catalyst-solvent-
       dopant systems and phys. properties)
     10043-11-5 HCA
     Boron nitride (BN) (CA INDEX NAME)
```

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Section cross-reference(s): 76
    crystn sintering cubic boron nitride ceramic property;
ST
    catalyst solvent dopant system boron nitride
    crystn sintering; semiconductor ceramic cubic boron
    nitride crystn sintering
ΤT
    Ceramics
        (boron nitride; crystn. and sintering of cubic boron
        nitride in catalyst-solvent-dopant systems
        and phys. properties)
    Semiconductor materials
ΤТ
     Semiconductor materials
        (ceramic, boron nitride; crystn. and sintering of cubic
       boron nitride in catalyst-solvent-dopant
        systems and phys. properties)
    Crystal growth
IT
    Crystal nucleation
    Crystallization
    Sintering
        (crystn. and sintering of cubic boron nitride in
        catalyst-solvent-dopant systems and phys.
        properties)
IΤ
    Structural phase transition
        (hexagonal-to-cubic; crystn. and sintering of
        cubic boron nitride in catalyst-solvent-
        dopant systems and phys. properties)
    Ceramics
ΙT
    Ceramics
        (semiconductors, boron nitride; crystn. and sintering of
        cubic boron nitride in catalyst-solvent-
        dopant systems and phys. properties)
IT
    1333-74-0D, Hydrogen, compds., uses
                                         7727-37-9D, Nitrogen, compds.,
    uses
        (additive; crystn. and sintering of cubic boron nitride
        in catalyst-solvent-dopant systems and phys.
        properties)
    12007-25-9, Magnesium diboride 26134-62-3, Lithium
IT
    nitride li3n
        (catalyst-solvent; crystn. and sintering of
        cubic boron nitride in catalyst-solvent-
        dopant systems and phys. properties)
IT
    10043-11-5, Boron nitride, processes
        (cubic, ceramics; crystn. and sintering of
        cubic boron nitride in catalyst-solvent-
       dopant systems and phys. properties)
    7440-21-3, Silicon, processes 7440-36-0, Antimony, processes
ΙT
    7440-38-2, Arsenic, processes 7440-69-9, Bismuth, processes
     7723-14-0, Phosphorus, processes
        (dopant; crystn. and sintering of cubic boron
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# nitride in **catalyst**-solvent-**dopant** systems and phys. properties)

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- L65 ANSWER 3 OF 9 HCA COPYRIGHT 2009 ACS on STN
- 127:73157 Original Reference No. 127:13851a,13854a Gas-source molecular beam epitaxy of III-V nitrides. Davis, R. F.; Paisley, M. J.; Sitar, Z.; Kester, D. J.; Ailey, K. S.; Linthicum, K.; Rowland, L. B.; Tanaka, S.; Kern, R. S. (Department of Materials Science and Engineering, North Carolina State University, Raleigh, NC, 27695-7907, USA). Journal of Crystal Growth, 178(1/2), 87-101 (English) 1997. CODEN: JCRGAE. ISSN: 0022-0248. Publisher: Elsevier.
- AB Amorphous, hexagonal and cubic phases of BN were grown via ion beam assisted deposition on Si(100) substrates. Gas-source MBE of the III-V nitrides is reviewed with 86 refs. Sapphire(0001) is the most commonly employed substrate with 6H-SiC(0001), ZnO(111) and Si(111) also being used primarily for the growth of wurtzite GaN(0001) in tandem with previously deposited GaN(0001) or AlN(0001) buffer layers. Si(001), GaAs(001), GaP(001) and 3C-SiC(001) were employed for growth of cubic (zincblende)  $\beta$ -GaN(001). The precursor materials are evapd. metals and reactive N species produced either via ECR or RF plasma decompn. of N2 or from NH3. However, point defect damage from the

plasma-derived species resulted in a steady increase in the no. of investigators now using NH3. The growth temps. for wurtzite GaN have increased from  $650 \pm 50^{\circ}$  to  $800 \pm 50^{\circ}$  to enhance the surface mobility of the reactants and, in turn, the efficiency of decompn. of NH3 and the microstructure and the growth rate of the films. Doping was achieved primarily with Si (donor) and Mg (acceptor); the latter was activated without post-growth annealing. Simple heterostructures, a p-n junction LED and a modulation-doped field-effect transistor were achieved using GSMBE-grown material. 10043-11-5, Boron nitride (BN), processes (gas-source MBE of) 10043-11-5 HCA Boron nitride (BN) (CA INDEX NAME)  $B \!\! \equiv \!\! = \!\! N$ **7439-95-4**, Magnesium, uses (gas-source MBE of Group IIIA nitrides doped with) 7439-95-4 HCA Magnesium (CA INDEX NAME) .75-0 (Crystallography and Liquid Crystals) Electron acceptors (gas-source MBE of Group IIIA nitrides doped with magnesium acceptor) Electron donors (gas-source MBE of Group IIIA nitrides doped with silicon donor) Field effect transistors (modulation-doped; gas-source MBE of III-V nitrides in fabrication of) 10043-11-5, Boron nitride (BN), processes (gas-source MBE of) **7439-95-4**, Magnesium, uses 7440-21-3, Silicon, uses (gas-source MBE of Group IIIA nitrides doped with) (1) Aktas, O; Electron Lett 1995, V31, P1389 (2) Basu, S; J Mater Res 1994, V9, P2370 HCA (3) Beresford, R; J Vac Sci Technol B 1995, V13, P792 HCA (4) Botchkarev, A; J Appl Phys 1995, V77, P4455 HCA (5) Carter, C; Mater Res Soc Proc 1986, V46, P693

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IT

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CN

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CC ΙT

ΙT

ΙT

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IT

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- L65 ANSWER 4 OF 9 HCA COPYRIGHT 2009 ACS on STN
- 125:72187 Original Reference No. 125:13513a,13516a Recent advances in the growth, doping, and characterization of III-V nitride thin films. Davis, Robert F.; Ailey, K. S.; Bremser, M. D.; Carlson, E.; Kern, R. S.; Kester, D. J.; Perry, W. G.; Tanaka, S.; Weeks, T. W., Jr. (Dep. mater. Sci. Eng., North Carolina State Univ., Raleigh, NC, 27695, USA). Festkoerperprobleme, 35, 1-24 (English) 1996. CODEN: FSTKA2. ISSN: 0430-3393. Publisher: Vieweg.
- AB BN films were grown on (100) surfaces of Si and diamond via ion beam assisted deposition (IBAD) using electron beam evapn. of B together with N and Ar bombardment at substrate temps. of 200-700° and an ion flux of 0.20-0.30 mA/cm2 FTIR spectroscopy and high-resoln. TEM (HRTEM) usually showed a growth sequence of amorphous (a-

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BN), hexagonal (h-BN), and
cubic (c-BN) layers. This sequence was
attributed to the increasing biaxial compressive stress with film
thickness due to ion bombardment and some interstitial Ar
incorporation. Single phase c-BN was
obtained at substrate temps. of 200-300°. The growth mode
and interfacial defects of AlN films grown on \alpha(6H)-SiC(0001)
substrates by plasma-assisted gas source MBE was investigated.
flat AlN surfaces indicative of 2-dimensional growth were obtained
using on-axis substrates and island-like features were obsd. on the
vicinal surfaces. The coalescence of these features gave rise to
double positioning boundaries because of the misalignment of the
Si/C bilayer steps with the Al/N bilayers of the growing film; the
quality of the thicker AlN films depended on the concn. of these
boundaries. Monocrystalling GaN and AlxGa1-xN(0001)(0 < x < 1)
films were grown via MOVPE on fresh prepd. high-temp. AlN(0001)
buffer layers using Et3Ga, Et3Al, and NH3 in a cold-wall, vertical
pancake-style reactor. The photoluminescence spectrum of GaN showed
strong near band edge emission with a FWHM value of 4 meV.
Cathodoluminescence spectra of AlxGa1-xN films for x < 0.5 also
showed intense near band-edge emission. The dislocation d. within
the 1st 0.5 \mum was 1 + 109 cm-2; it decreased with
increasing film thickness. Double-crystal x-ray rocking curves
(DCXRC) indicated a FWHM value of 66 arc sec for the pure GaN(0004)
reflection; this value increased with increasing x. Controlled
n-type Si-doping of GaN was achieved for net carrier
concns. ranging from 1 + 1017 cm-3 to 1 + 1020 cm-3.
Si-doped Al0.75Ga0.25N exhibited neg. electron affinity.
Mg-doped, p-type GaN was achieved with na-nd = 3
+ 1017, \rho = 7 \Omega cm and \mu = 3 cm2/V s.
                                       The
sections of the III-V nitrides are preceded by a survey of growth
techniques and properties.
7439-95-4, Magnesium, uses
   (Si- and Mg-doping of GaN, photo- and
   cathodoluminescence spectra of undoped and doped GaN,
   and elec. properties of Si:GaN)
7439-95-4 HCA
Magnesium (CA INDEX NAME)
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CN Boron nitride (BN) (CA INDEX NAME)

ΙT

RN CN

Mg

#### $B \equiv N$

- CC 75-1 (Crystallography and Liquid Crystals)
  Section cross-reference(s): 73
- IT Luminescence

Luminescence, cathodo-

(Si- and Mg-doping of GaN and photo- and cathodoluminescence spectra of undoped and doped GaN)

IT Electron affinity

(electron affinity of Si-doped Al0.75Ga0.25N)

IT Electric property

(of Si-doped GaN)

IT Epitaxy

(metalorg. vapor-phase, MOVPE of GaN and AlxGal-xN on AlN buffer layers, Si- and Mg-doping of GaN and photo- and cathodoluminescence spectra of undoped and doped GaN)

IT 25617-97-4, Gallium nitride 106097-44-3, Aluminum gallium nitride ((Al,Ga)N)

(MOVPE of GaN and AlxGal-xN on AlN buffer layers, si- and Mg-doping of GaN, photo- and cathodoluminescence spectra of undoped and doped GaN, and elec. properties of Si:GaN)

- TT 7439-95-4, Magnesium, uses 7440-21-3, Silicon, uses
   (Si- and Mg-doping of GaN, photo- and
   cathodoluminescence spectra of undoped and doped GaN,
   and elec. properties of Si:GaN)
- IT 153809-73-5, Aluminum gallium nitride (Al3GaN4) (electron affinity of Si-doped)
- IT 10043-11-5, Boron nitride, properties (electron beam evapn. of BN on Si and diamond and its characterization by FTIR spectrometry and TEM)
- L65 ANSWER 5 OF 9 HCA COPYRIGHT 2009 ACS on STN
- 124:267947 Original Reference No. 124:49467a,49470a Micron-size cBN powder produced by HP/HT synthesis. Fecioru, Marian; Dinca, Gabriel; Georgeoni, Paul; Calu, Georgeta; Baluta, Gheorghe; Deju, Marinela ("DACIA" Synthetic Diamond Factory, Bucharest, Rom.). Advances in New Diamond Science and Technology, International Conference on New Diamond Science and Technology, 4th, Kobe, Japan, July 18-22, 1994, 559-62. Editor(s): Saito, S. Scientific Publishing Division of MYU: Tokyo, Japan. (English) 1994. CODEN: 62PAAT.
- AB The feasibility of prepg. fine **cBN** powder by **catalytic** synthesis at high static pressure was investigated. The effect of process parameters, **hBN** characteristics, and type of **catalyst** on the yield, size

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ΙT

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distribution, shape, and purity of micron-size cBN grit
     was evaluated. The properties were examd. by optical microscopy,
     SEM, x-ray diffraction, emission spectrophotometry, and particle
     size anal.
     10043-11-5, Boron nitride, processes
        (cubic; micron-size cBN powder produced by
       hot pressing of hexagonal boron
       nitride in presence of phase-transfer catalyst)
     10043-11-5 HCA
     Boron nitride (BN) (CA INDEX NAME)
B \equiv N
     57-2 (Ceramics)
     catalyst cubic boron nitride
     powder; hot pressing hexagonal boron
     nitride; phase transition
     catalyst boron nitride; melamine magnesium catalyst
     ; magnesium diboride nitride catalyst; calcium nitride
     lithium fluoride catalyst; lithium nitride
     catalyst
     Sintering
       (hot pressing, micron-size cBN powder produced by hot
       pressing of hexagonal boron nitride
        in presence phase transition catalyst
     Catalysts and Catalysis
        (phase-transfer, micron-size cBN powder produced by hot
       pressing of hexagonal boron nitride
        in presence of)
     12057-71-5, Magnesium nitride
        (admixts. with ammonium fluoride, phase-transfer
       catalysts; micron-size cBN powder produced by
       hot pressing of hexagonal boron
       nitride in presence of)
     7789-24-4, Lithium fluoride, uses
        (admixts. with calcium nitride, phase-transfer catalysts
        ; micron-size cBN powder produced by hot pressing of
       hexagonal boron nitride in presence
     12013-82-0, Calcium nitride (Ca3N2)
        (admixts. with lithium fluoride, phase-transfer catalysts
        ; micron-size cBN powder produced by hot pressing of
       hexagonal boron nitride in presence
     12125-01-8, Ammonium fluoride
        (admixts. with magnesium nitride,
```

phase-transfer catalysts; micron-size cBN
powder produced by hot pressing of hexagonal
boron nitride in presence of)

IT 7439-95-4, **Magnesium**, uses

(admixts. with melamine, phase-transfer catalysts; micron-size cBN powder produced by hot pressing of hexagonal boron nitride in presence of)

IT 10043-11-5, Boron nitride, processes
 (cubic; micron-size cBN powder produced by
 hot pressing of hexagonal boron
 nitride in presence of phase-transfer catalyst)

- 12007-25-9, Magnesium diboride 26134-62-3, Lithium nitride (phase-transfer catalyst; micron-size cBN powder produced by hot pressing of hexagonal boron nitride in presence of)
- L65 ANSWER 6 OF 9 HCA COPYRIGHT 2009 ACS on STN

  124:161412 Original Reference No. 124:29670h,29671a Electrical properties of boron nitride thin films grown by neutralized nitrogen ion assisted vapor deposition. Lu, Ming; Bousetta, A.; Bensaoula, A.; Waters, K.; Schultz, J. A. (Space Vacuum Epitaxy Cent., Univ. Houston, Houston, TX, 77204-5507, USA). Applied Physics Letters, 68(5), 622-4 (English) 1996. CODEN: APPLAB. ISSN: 0003-6951. Publisher: American Institute of Physics.
- BN thin films (contg. mixed c-BN/h-BN phase) were deposited on Si(100) substrates using neutralized N beam and electron beam evapn. of B. All as-deposited BN films were p-type with a room-temp. carrier concn. at 5 + 1016-1 + 1017 cm-3. The Mg-doped BN films showed carrier concns. in the range of 1.2 + 1018 cm-3 to 5.2 + 1018 cm-3 when the Mg cell temp. was varied from 250 to 500°. The films were analyzed for both majority elements (B and N) and dopant/impurity (Si, Mg, Fe, etc.) incorporation using SIMS and mass spectroscopy of recoiled ions (MRSI). MRSI is superior for dopant characterization of BN thin films.
- CN Magnesium (CA INDEX NAME)

Mg

CC 76-1 (Electric Phenomena)

ST plasma CVD boron nitride elec property; hole magnesium doping boron nitride film

IT 7439-95-4, Magnesium, processes

(elec. properties of boron nitride thin films grown by neutralized nitrogen ion-assisted vapor deposition)

L65 ANSWER 7 OF 9 HCA COPYRIGHT 2009 ACS on STN
119:166171 Original Reference No. 119:29645a,29648a Synthesis of
cubic boron nitride using magnesium and
pure or M'-doped lithium nitride, calcium nitride and
magnesium nitride with M' = aluminum, boron, silicon, titanium.
Bocquillon, G.; Loriers-Susse, C.; Loriers, J. (Lab. Physicochim.
Mater., CNRS, Meudon, 92195, Fr.). Journal of Materials Science,
28(13), 3547-56 (English) 1993. CODEN: JMTSAS. ISSN:
0022-2461.

The growth pressure temp. region of cubic boron AΒ nitride (cBN) in the systems Mg-BN and MxNy-BN (MxNy = Li3N, Ca3N2, Mg3N2) has been redetd. using well-crystd. hexagonal BN (hBN) with low oxygen content (0.2%) as the starting material. The data on the MxNy-BN systems are compatible with the existence of two growth regions: a high-temp. region where cBN grows from a liq. phase, and a low-temp. region where cBN forms from solid-solid reactions. Previous data are discussed according to this model and possible solid-state reactions are proposed on the basis of thermodn. considerations. The results for the Mg-BN system confirm the effect of the O2 content of the starting BN on the **cBN** growth region. The systems (MxNy + M')-BN (M' = Al, B,Si, Ti) produce cBN crystals of increased size and improved morphol. (more compact and perfect) compared to those obtained with the MxNy-BN systems. Their color is dark or black and their size reaches 0.6 mm. The effect of the relative proportions of M' and MxNy on the growth region and yield has been detd. and is discussed on the basis of the chem. reactions likely to occur.

IT 10043-11-5P, Boron nitride, preparation

(cubic, prepn. of, in magnesium and pure or doped lithium nitride and calcium nitride and magnesium nitride systems)

RN 10043-11-5 HCA

CN Boron nitride (BN) (CA INDEX NAME)

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IT
     12057-71-5, Magnesium nitride (Mg3N2)
     26134-62-3, Lithium nitride Li3N
        (systems, hexagonal boron nitride-,
        cubic boron nitride formation in)
     12057-71-5 HCA
RN
     Magnesium nitride (Mg3N2) (CA INDEX NAME)
CN
*** STRUCTURE DIAGRAM IS NOT AVAILABLE ***
     26134-62-3 HCA
RN
    Lithium nitride (Li3N) (CA INDEX NAME)
CN
   Li
Li-N-Li
     7439-95-4, Magnesium, properties
ΤT
       .(systems, hexagonal boron nitride-,
        cubic boron nitride formation in)
     7439-95-4 HCA
RN
     Magnesium (CA INDEX NAME)
CN
Mg
     57-2 (Ceramics)
CC
     Section cross-reference(s): 49
     cubic boron nitride prepn; magnesium
ST
     system cubic boron nitride prepn;
     lithium nitride system boron nitride prepn; calcium nitride system
     boron nitride prepn
     10043-11-5P, Boron nitride, preparation
IT
        (cubic, prepn. of, in magnesium and pure or
        doped lithium nitride and calcium nitride and magnesium
        nitride systems)
ΙT
     7429-90-5, Aluminum, uses 7440-21-3, Silicon, uses 7440-32-6,
     Titanium, uses 7440-42-8, Boron, uses
        (dopant, in hexagonal boron
       nitride system, cubic-phase crystal
        size and morphol. in relation to)
     12013-82-0, Calcium nitride Ca3N2 12057-71-5, Magnesium
IT
     nitride (Mg3N2) 26134-62-3, Lithium nitride Li3N
        (systems, hexagonal boron nitride-,
        cubic boron nitride formation in)
IT
     7439-95-4, Magnesium, properties
        (systems, hexagonal boron nitride-,
        cubic boron nitride formation in)
     ANSWER 8 OF 9 HCA COPYRIGHT 2009 ACS on STN
L65
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118:65431 Original Reference No. 118:11529a,11532a Manufacture of polycrystalline cubic boron nitride from graphitic boron nitride in the absence of bulk-catalytic material, and the boron nitride obtained. Corrigan, Francis Raymond (General Electric Co., USA). Eur. Pat. Appl. EP 512762 A2 19921111, 7 pp. DESIGNATED STATES: R: AT, BE, CH, DE, FR, GB, LI, SE. (English). CODEN: EPXXDW. APPLICATION: EP 1992-303949 19920430. PRIORITY: US 1991-695380 19910503.
```

The process comprises doping the graphitic (
hexagonal, pyrolytic) BN (GBN, HBN, PBN)
with .ltorsim.50 wt.% non-BN atoms or atom clusters, an amt. of
which being included in the cubic BN (
CBN) lattice, to lower the high-pressure conditions required
in the manuf. of CBN in the absence of those atoms or atom
clusters. Zr-doped HBN samples were hot pressed
at at 1800° and 65 kbar and showed complete conversion, vs.
partial conversion at 60 kbar and complete conversion for undoped
HBN at 68 kbar.

RN 7439-95-4 HCA

CN Magnesium (CA INDEX NAME)

Mg

RN 12795-15-2 HCA

CN Magnesium boride (CA INDEX NAME)

Co	omponent	Ratio	   	Component Registry Number
B Mg		x x	+   	7440-42-8 7439-95-4
RN	26134-62-3	нса		

Lithium nitride (Li3N) (CA INDEX NAME)

CN

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56127-34-5 HCA
RN
     Magnesium nitride (CA INDEX NAME)
CN
                      Ratio
                                         Component
  Component
                                      Registry Number
                                           17778-88-0
Ν
                        х
                                            7439-95-4
Mg
                        x
     10043-11-5P, Boron nitride, preparation
IT
        (manuf. of cubic, from graphitic boron
        nitride, dopants for phase
        transition in, for decreased pressure)
     10043-11-5 HCA
RN
     Boron nitride (BN) (CA INDEX NAME)
CN
B \equiv N
IC
     ICM C04B035-58
     57-2 (Ceramics)
CC
ST
     boron nitride phase transition dopant;
     hexagonal cubic phase transition
     ; zirconium dopant phase transition;
     silicon dopant phase transition;
     titanium dopant phase transition
ΙT
     Group IVA elements
     Group VA elements
     Group VIA elements
     Transition metals, uses
        (dopants, in hexagonal-cubic
        phase transition of boron nitride, for
        decreased pressure)
     Phase transition
ΙT
        (hexagonal-cubic, of boron, dopants
        for, for decreased pressure)
     7429-90-5, Aluminum, uses 7439-95-4, Magnesium,
ΙT
     uses 7440-21-3, Silicon, uses 7440-32-6, Titanium, uses
                              7440-67-7, Zirconium, uses 12070-08-5,
     7440-44-0, Carbon, uses
                        12619-90-8, Nickel boride 12795-15-2,
     Titanium carbide
                        25583-20-4, Titanium nitride
     Magnesium boride
     26134-62-3, Lithium nitride 37367-77-4, Aluminum boride
     56127-34-5, Magnesium nitride
        (dopant, in hexagonal-cubic
        phase transition of boron nitride, for
        decreased pressure)
IT
     10043-11-5P, Boron nitride, preparation
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(manuf. of cubic, from graphitic boron

# nitride, dopants for phase transition in, for decreased pressure)

49-5 (Industrial Inorganic Chemicals)

CC

ST

ANSWER 9 OF 9 HCA COPYRIGHT 2009 ACS on STN 93:49538 Original Reference No. 93:8175a,8178a Effect of process parameters and dopants in the synthesis on the mechanical properties of diamond grains and cubic boron Drexler, J.; Kupcik, F. (Vyzkum. Ustav Praskovou nitride. Metal., Sumperk, Czech.). Medzinar. Konf. Praskovej Metal., [Zb. Prednasok], 5th, Volume 1, 219-40. Slov. Akad. Vied, Ustav Exp. Metal.: Kosice, Czech. (Czech) 1978. CODEN: 42SXAN. The effects of temp. and pressure on both the graphite to diamond AΒ and the hexagonal to cubic B nitride conversion are similar, the conversion degrees and the phase transformation rates increasing with the increasing pressure. Graphite was converted to diamond in the presence of Ni-Mn solvent at 5.2-6.5 GPa and 1500-2000 K. Max. conversion is in the region of Ni:Mn wt. ratio of .apprx.1, whereas min. conversion values are obsd. in the regions of the Ni2Mn and NiMn2 intermetallic compd. formation. Hexagonal B nitride was converted to the cubic form in a mixt. with Mg at 5.2-5.8 GPa in the Belt high-pressure device. The grain size and mech. properties of both products decrease with increasing pressure at which the conversion takes place, as the pressure aids in the no. of the cryst. nuclei formed increase. The grain size and mech. properties can be improved through the use of additives, the compn. and amt. of which, however, are not specified. ΙT 7439-95-4, uses and miscellaneous (in boron nitride hexagonal-tocubic transformation) 7439-95-4 HCA RN CNMagnesium (CA INDEX NAME) Mg IT **10043-11-5P**, preparation (prepn. of cubic, from hexagonal form, dopants and process parameters in relation to) 10043-11-5 HCA RNBoron nitride (BN) (CA INDEX NAME) CN  $B \equiv N$ 

diamond prepn; graphite diamond transformation; manganese nickel

solvent catalyst; boron nitride cryst transformation;

```
magnesium catalyst
     37233-01-5
ΙT
        (catalyst and solvent, in diamond prepn. from graphite)
     7439-95-4, uses and miscellaneous
ΙT
        (in boron nitride hexagonal-to-
        cubic transformation)
IT
     10043-11-5P, preparation
        (prepn. of cubic, from hexagonal form,
        dopants and process parameters in relation to)
     7782-40-3P, preparation
IT
        (prepn. of, from graphite, dopants and process
        parameters in relation to)
=> D L66 1-15 CBIB ABS HITSTR HITIND RE
L66 ANSWER 1 OF 15 HCA COPYRIGHT 2009 ACS on STN
137:281453 Manufacture of cubic boron
     nitride from hexagonal boron
     nitride.. Iizuka, Makoto (Showa Denko K. K., Japan).
     Kokai Tokkyo Koho JP 2002284511 A 20021003, 7 pp.
     (Japanese). CODEN: JKXXAF. APPLICATION: JP 2001-89029 20010327.
AΒ
     In title process including keeping hexagonal BN
     (h-BN) in thermal dynamically stable region of
     cubic BN (c-BN) in the
     presence of catalyst for transformation of h-
     BN to c-BN, the catalyst is
     selected from ≥ 1 of LiMBN2 (where M is Ca, Sr, Ba, Ra, Be or
     Mg), and alkali metal, alk. earth metal and their nitride or
     boronitride. In addn., the oxygen content of the LiMBN2 is \leq
     1 %; the oxygen content of the alkali metal, alk. earth metal, and
     their nitride or boronitride is ≤ 1 %. The LiMBN2 is LiCaBN2
     and/or LiBaBN2. The alkali metal boronitride is Li3BN2.
                                                                The alk.
     earth metal boronitride is Ca3B2N4. The catalyst contains
     LiCaBN2 and Li3BN2. Grinding wheels made of the manufd. c
     -BN is claimed.
     10043-11-5P, Boron nitride, preparation
IT
        (cubic; manuf. of cubic boron
       nitride from hexagonal boron
       nitride)
RN
     10043-11-5 HCA
     Boron nitride (BN) (CA INDEX NAME)
CN
B \equiv N
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TT 7439-93-2, Lithium, uses 7439-95-4, Magnesium, uses 12057-71-5, Magnesium nitride (Mg3N2)

```
12408-97-8 26134-62-3, Lithium nitride (Li3N)
     87354-58-3, Calcium lithium boride nitride (CaLiBN2)
     461638-65-3, Barium boron lithium nitride (BaBLiN2)
        (manuf. of cubic boron nitride from
       hexagonal boron nitride)
     7439-93-2 HCA
RN
    Lithium (CA INDEX NAME)
CN
Li
RN
    7439-95-4 HCA
    Magnesium (CA INDEX NAME)
CN
Ma
     12057-71-5 HCA
RN
    Magnesium nitride (Mg3N2) (CA INDEX NAME)
*** STRUCTURE DIAGRAM IS NOT AVAILABLE ***
    12408-97-8 HCA
RN
    Boranamine, 1-imino-, trilithium salt (9CI) (CA INDEX NAME)
CN
H_2N-B=NH
 ●3 Li
RN
    26134-62-3 HCA
CN
    Lithium nitride (Li3N) (CA INDEX NAME)
  Li
Li-N-Li
RN
    87354-58-3 HCA
CN
    Boranamine, 1-imino-, calcium lithium salt (1:1:1) (9CI) (CA INDEX
    NAME)
```

 $H_2N-B=NH$ 

Ca

Li

461638-65-3 HCA RN

CN Barium boron lithium nitride (BaBLiN2) (CA INDEX NAME)

	mpone	nt     	Ratio		Component Registry Number
==== N		=====+================================	-= 2	+ 	17778-88-0
В		İ	1	i	7440-42-8
Ba		i	1	i	7440-39-3
Li		İ	1	i	7439-93-2
IC	ICM	C01B021-064			
	ICS	B01J003-00;	B01J027-24	; C09E	<003-14
CC	49-5	(Industrial	Inorganic	Chemic	cals)
	Sect:	ion cross-re	ference(s):	57, 6	57
СT		_ b		•	

cubic boron nitride manuf STcatalyst; hexagonal boron

nitride transformation cubic boron

nitride manuf catalyst

IT Catalysts

> Phase transfer catalysts Structural phase transition

> > (manuf. of cubic boron nitride from

hexagonal boron nitride)

Grinding wheels IT

(prodn. of cubic boron nitride from

hexagonal boron nitride for)

ΙT 10043-11-5P, Boron nitride, preparation

> (cubic; manuf. of cubic boron nitride from hexagonal boron

nitride)

IT 7439-93-2, Lithium, uses 7439-95-4, Magnesium, uses 12057-71-5, Magnesium nitride (Mg3N2) 12408-97-8 26134-62-3, Lithium nitride (Li3N) 29285-24-3, Potassium nitride (K3N) 65453-51-2, Calcium boride nitride (Ca3B2N4) **87354-58-3**, Calcium lithium boride nitride (CaLiBN2) **461638-65-3**, Barium boron lithium

nitride (BaBLiN2)

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(manuf. of cubic boron nitride from
        hexagonal boron nitride)
    ANSWER 2 OF 15 HCA COPYRIGHT 2009 ACS on STN
137:267127 Method for manufacturing cubic boron
     nitride. Iizuka, Makoto (Showa Denko K.K., Japan).
     Int. Appl. WO 2002076906 A2 20021003, 25 pp. DESIGNATED
                AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BY, BZ, CA,
     STATES: W:
     CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, ES, FI, GB, GD, GE,
    GH, GM, HR, HU, ID, IL, IN, IS, KE, KG, KR, KZ, LC, LK, LR, LS, LT,
    LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ, NO, NZ, OM, PH, PL, PT, RO,
     RU, SD, SE, SG, SI, SK, SL, TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ,
     VN, YU, ZA, ZM, ZW, AM, AZ, BY, KG, KZ, MD, RU, TJ, TM; RW: AT, BE,
     BF, BJ, CF, CG, CH, CI, CM, CY, DE, DK, ES, FI, FR, GA, GB, GR, IE,
     IT, LU, MC, ML, MR, NE, NL, PT, SE, SN, TD, TG, TR. (English).
                    APPLICATION: WO 2002-JP2987 20020327. PRIORITY: JP
    CODEN: PIXXD2.
     2001-89029 20010327; US 2001-280749P 20010403.
    A method for producing c-boron nitride
AΒ
     includes maintaining h-boron nitride
     in the presence of a catalyst substance under conditions
    where cubic boron nitride remains
    thermodynamically stable to thereby transform hexagonal
    boron nitride into cubic boron
    nitride, wherein the catalyst substance contains
    LiMBN2, in which M represents Ca, Sr, Ba, Ra, Be, or Mg, and at
    least one species selected from the group consisting of alkali
    metals, alk. earth metals, nitrides thereof and boronitrides
    thereof. Any one of the LiMBN2, alkali metals, alk. earth metals,
    nitrides thereof and boronitrides thereof has an oxygen content of
           The percent transformation into cubic
    boron nitride can be considerably enhanced, and
    the cubic boron nitride obtained
    exhibits high mech. strength.
IT
    10043-11-5, Boron nitride, processes
        (cubic an hexagonal crystal structure; method
        for manufg. c-BN by catalytic
       phase transformation of h-BN
RN
    10043-11-5 HCA
CN
    Boron nitride (BN)
                        (CA INDEX NAME)
B \equiv N
```

7439-93-2, Lithium, uses 7439-95-4, Magnesium,

IT

```
uses 12057-71-5, Magnesium nitride (Mg3N2)
     12408-97-8 12521-66-3 26134-62-3,
     Lithium nitride (Li3N) 71330-55-7, Magnesium boride
     nitride (Mg3B2N4) 87354-58-3, Calcium lithium boride
     nitride (CaLiBN2) 161565-26-0, Boron lithium magnesium
     nitride (BLiMgN2) 461638-64-2, Boron lithium strontium
     nitride (BLiSrN2) 461638-65-3, Barium boron lithium
     nitride (BaBLiN2) 461638-66-4, Lithium radium boride
     nitride (LiRaBN2) 461638-67-5, Beryllium boron lithium
     nitride (BeBLiN2)
        (method for manufg. c-BN by catalytic
        phase transformation of h-BN
        )
     7439-93-2 HCA
RN
CN
     Lithium (CA INDEX NAME)
Li
     7439-95-4 HCA
RN
CN
     Magnesium (CA INDEX NAME)
Mq
     12057-71-5 HCA
RN
     Magnesium nitride (Mg3N2) (CA INDEX NAME)
*** STRUCTURE DIAGRAM IS NOT AVAILABLE ***
     12408-97-8 HCA
RN
     Boranamine, 1-imino-, trilithium salt (9CI) (CA INDEX NAME)
CN
H_2N-B=NH
 ●3 Li
RN
     12521-66-3 HCA
CN
     Silanetetramine, octalithium salt (9CI) (CA INDEX NAME)
```

●8 Li

RN 26134-62-3 HCA CN Lithium nitride (Li3N) (CA INDEX NAME)

RN 71330-55-7 HCA CN Boranamine, 1-imino-, magnesium salt (2:3) (9CI) (CA INDEX NAME)

 $H_2N-B=NH$ 

# ●3/2 Mg

RN 87354-58-3 HCA
CN Boranamine, 1-imino-, calcium lithium salt (1:1:1) (9CI) (CA INDEX NAME)

 $H_2N-B=NH$ 

● Ca

● Li

RN 161565-26-0 HCA CN Boron lithium magnesium nitride (BLiMgN2) (CA INDEX NAME)

Component		Ratio		Component Registry Number
	==+==		=+=	
N		2		17778-88-0
В	Ì	1	1	7440-42-8
Mg	1	1	1	7439-95-4
Li	1	1	l	7439-93-2

RN 461638-64-2 HCA

CN Boron lithium strontium nitride (BLiSrN2) (CA INDEX NAME)

Component	Ratio	Component   Registry Number
==========	-+==========	+======================================
N	2	17778-88-0
В	1	7440-42-8
Sr	1	7440-24-6
Li	1	7439-93-2

RN 461638-65-3 HCA

CN Barium boron lithium nitride (BaBLiN2) (CA INDEX NAME)

Component		Ratio	Component egistry Number	
==========	==+===		====+===	
N	1	2	1	17778-88-0
В	1	1	1	7440-42-8
Ва	1	1	1	7440-39-3
Li	1	1	1	7439-93-2

RN 461638-66-4 HCA

CN Lithium radium boride nitride (LiRaBN2) (9CI) (CA INDEX NAME)

Component	    1	Ratio	    -	Component Registry Number
			· T	
N		2	1	17778-88-0
В	1	1		7440-42-8
Ra		1		7440-14-4
Li		1	1	7439-93-2

RN 461638-67-5 HCA

CN Beryllium boron lithium nitride (BeBLiN2) (CA INDEX NAME)

Component	Ratio	.	Compon	ent
_	1	1	Registry	Number
	_			

```
Ν
                        2
                                            17778-88-0
                        1
В
                                             7440-42-8
Ве
                        1
                                             7440-41-7
                                             7439-93-2
Li
IC
     ICM C04B035-5831
CC
     57-2 (Ceramics)
     Section cross-reference(s): 67
ST
     cubic boron nitride synthesis
     hexagonal crystal structure transition strength
     Nitrides
IT
        (boronitrides; method for manufg. c-BN by
        catalytic phase transformation of
        h-BN)
IT
     Crystal structure types
        (cubic, boron nitride; method for
        manufg. c-BN by catalytic
        phase transformation of h-BN
ΙT
     Crystal structure types
        (hexagonal, boron nitride; method
        for manufg. c-BN by catalytic
        phase transformation of h-BN
ΙT
     Abrasives
       Catalysts
     Cutting tools
     Particle size
       Phase transition
     Strength
        (method for manufg. c-BN by catalytic
        phase transformation of h-BN
IT
     Alkali metals, uses
     Alkaline earth metals
        (method for manufg. c-BN by catalytic
       phase transformation of h-BN
IT
     10043-11-5, Boron nitride, processes
        (cubic an hexagonal crystal structure; method
        for manufg. c-BN by catalytic
       phase transformation of h-BN
ΙT
     7439-93-2, Lithium, uses 7439-95-4, Magnesium,
     uses 12057-71-5, Magnesium nitride (Mg3N2)
                12514-90-8 12521-66-3
     12408-97-8
    26134-62-3, Lithium nitride (Li3N)
                                          29285-24-3, Potassium
                     65453-51-2, Calcium boride nitride (Ca3B2N4)
     nitride (K3N)
```

```
71330-55-7, Magnesium boride nitride (Mg3B2N4)
     87354-58-3, Calcium lithium boride nitride (CaLiBN2)
     161565-26-0, Boron lithium magnesium nitride (BLiMgN2)
     461638-64-2, Boron lithium strontium nitride (BLiSrN2)
     461638-65-3, Barium boron lithium nitride (BaBLiN2)
     461638-66-4, Lithium radium boride nitride (LiRaBN2)
     461638-67-5, Beryllium boron lithium nitride (BeBLiN2)
        (method for manufg. c-BN by catalytic
       phase transformation of h-BN
RE
(1) Anon; US 4551316 A HCA
    ANSWER 3 OF 15 HCA COPYRIGHT 2009 ACS on STN
130:354316 Alkali metal and alkaline earth metal compounds in
    preparation of cubic boron nitride
    from hexagonal boron nitride.
                                   Shioi,
    Kousuke; Ihara, Eiji (Showa Denko K. K., Japan). Ger. Offen. DE
     19854487 Al 19990527, 10 pp. (German). CODEN: GWXXBX.
    APPLICATION: DE 1998-19854487 19981125. PRIORITY: JP 1997-323352
    19971125.
AB
    A process for conversion of hexagonal boron
    nitride into cubic boron nitride
     , in which the hexagonal boron nitride
    is subjected to temp. and pressure conditions favoring stability of
    cubic nitride in the presence of at least one compd. chosen
    from alkali and alk. earth amides, imides, and carbides, as well as
    a silicon source and/or a boron source. Preferred amides and
    carbides are LiNH2 and CaC2.
    1070-75-3, Lithium acetylide (Li2(C2)) 7782-89-0,
IT
    Lithium amide (LiNH2) 7803-54-5, Magnesium amide (Mg(NH2)2
    12122-46-2, Magnesium carbide 12135-01-2, Lithium
     imide (Li2(NH)) 26134-80-5, Magnesium imide (MqNH)
        (additive; alkali metal and alk. earth metal compds. in prepn. of
        cubic boron nitride from
       hexagonal boron nitride)
     1070-75-3 HCA
RN
    Lithium acetylide (Li2(C2)) (6CI, 7CI, 8CI, 9CI) (CA INDEX NAME)
CN
Li-C=C-Li
RN
    7782-89-0 HCA
    Lithium amide (Li(NH2)) (CA INDEX NAME)
Li-NH2
```

```
RN
     7803-54-5 HCA
     Magnesium amide (Mg(NH2)2) (7CI, 8CI, 9CI) (CA INDEX NAME)
CN
H_2N - Mq - NH_2
RN
     12122-46-2 HCA
     Magnesium acetylide (Mg(C2)) (CA INDEX NAME)
CN
RN
     12135-01-2 HCA
     Lithium imide (Li2(NH)) (9CI) (CA INDEX NAME)
CN
Li-NH-Li
RN
     26134-80-5 HCA
     Magnesium imide (Mg(NH)) (9CI) (CA INDEX NAME)
CN
Mq = NH
     10043-11-5P, Boron nitride, preparation
IT
        (cubic; alkali metal and alk. earth metal compds. in
        prepn. of cubic boron nitride from
        hexagonal boron nitride)
     10043-11-5 HCA
RN
CN
     Boron nitride (BN) (CA INDEX NAME)
B \equiv N
IC
     ICM C01B021-064
     ICS C30B029-38; C30B001-12
     49-8 (Industrial Inorganic Chemicals)
CC
     cubic boron nitride phase
ST
     transition; hexagonal cubic
     boron nitride phase transition
     ; alkali amide carbide boron nitride phase
     transition
     Organometallic compounds
IT
        (acetylides; alkali metal and alk. earth metal compds. in prepn.
        of cubic boron nitride from
        hexagonal boron nitride)
ΙT
     Alkali metal compounds
```

Alkaline earth compounds
(amides, imides, and carbides; alkali metal and alk. earth metal compds. in prepn. of cubic boron
nitride from hexagonal boron
nitride)

IT Structural phase transition
(hexagonal-to-cubic; alkali metal and alk.
earth metal compds. in prepn. of cubic boron
nitride from hexagonal boron
nitride)

75-20-7, Calcium carbide 1070-75-3, Lithium acetylide (Li2(C2)) 7440-21-3, Silicon, uses 7440-42-8, Boron, uses 7782-89-0, Lithium amide (LiNH2) 7803-54-5, Magnesium amide (Mg(NH2)2 12122-46-2, Magnesium carbide 12135-01-2, Lithium imide (Li2(NH)) 12400-28-1, Calcium imide (CaNH) 23321-74-6, Calcium amide (Ca(NH2)2 26134-80-5, Magnesium imide (MgNH) (additive; alkali metal and alk. earth metal compds. in prepn.

(additive; alkali metal and alk. earth metal compds. in prepn. of cubic boron nitride from hexagonal boron nitride)

- TT 7664-41-7D, Ammonia, alkali and alk. earth metal salts, uses 34846-56-5D, Acetylide (C22-), alkali and alk. earth metal salts (additives; alkali metal and alk. earth metal compds. in prepn. of cubic boron nitride from hexagonal boron nitride)
- IT 10043-11-5P, Boron nitride, preparation
   (cubic; alkali metal and alk. earth metal compds. in
   prepn. of cubic boron nitride from
   hexagonal boron nitride)
- L66 ANSWER 4 OF 15 HCA COPYRIGHT 2009 ACS on STN

  129:125644 Original Reference No. 129:25663a,25666a Boron nitride revisited. Will, G.; Nover, G.; Von Der Gonna, J. (Mineralogical Institute, Bonn University, Bonn, Germany). Koatsuryoku no Kagaku to Gijutsu, 7(Proceedings of International Conference--AIRAPT-16 and HPCJ-38--on High Pressure Science and Technology, 1997), 975-979 (English) 1998. CODEN: KKGIE2. ISSN: 0917-639X. Publisher: Nippon Koatsuryoku Gakkai.
- The phase diagram published by Bundy & Wentorf already shows cBN to be the stable form of boron nitride, in contrast to similar diagrams used today. This picture is supported by theor. calcns. by Maki et al. and Solozhenko. Results of compressibility measurements for cBN and hBN are presented. To clarify the picture of the phase diagram the transformation from hBN to cBN was studied in a series of time dependent diffraction expts. using synchrotron radiation. The crystn. is found to go through the melt. In a second series of expts. the back-transformation of cBN

to **hBN** was studied. Finally the exptl. conditions for high pressure/ high temp. synthesis of **cBN** could be lowered to 2.5 GPa at  $1800^{\circ}$  using amorphous boron nitride as starting material.

IT 26134-62-3P, Lithium nitride (Li3N) 67182-71-2P, Lithium boride nitride 71330-55-7P, Magnesium boride nitride (Mg3B2N4)

(synthesis of boron nitride and phase diagram studies)

RN 26134-62-3 HCA

CN Lithium nitride (Li3N) (CA INDEX NAME)

RN 67182-71-2 HCA

CN Lithium boride nitride (CA INDEX NAME)

Со	mponent	Rati	0	-	onent y Number			
N B Li	======+=:    · 	x x x x	     	7	778-88-0 440-42-8 439-93-2	<del>-</del>		
RN CN	71330-55-7 Boranamine,		magnesium	salt (2:	3) (9CI)	(CA	INDEX	NAME)

 $H_2N-B=NH$ 

### ●3/2 Mg

- CC 56-9 (Nonferrous Metals and Alloys)
- ST boron nitride synthesis compressibility **phase** diagram
- IT Compressibility

Crystallization

Phase diagram

Synchrotron radiation

Synthesis

(synthesis of boron nitride and phase diagram studies)

IT Metallic glasses

(synthesis of boron nitride and phase diagram studies)

IT 10043-11-5P, Boron nitride (BN), preparation **26134-62-3P**, Lithium nitride (Li3N) **67182-71-2P**, Lithium boride nitride

# 71330-55-7P, Magnesium boride nitride (Mg3B2N4) (synthesis of boron nitride and phase diagram studies)

RE

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- (3) Corrigan, F; No publication given 1975, V63, P3812 HCA
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- (10) Singh, B; J Crystal Growth 1995, V125, P143
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- (12) Solozhenko, V; High Pressure Research 1995, V13, Pxx
- (13) Solozhenko, V; Proceedings of the XV AIRAPT & XXXIII EHPRGG International Conference 1995, P405
- (14) Solozhenko, V; Solid State Communications 1994, V90, P65 HCA
- (15) Solozhenko, V; Solid State Communications 1995, V96, P1 HCA
- (16) Solozhenko, V; XXXII Annual meeting EHPRG, High pressure in Material Science and Geoscience 1994, P57
- (17) Von der Gonna, J; Solid State Communications, in Press
- (18) Wentorf, R; J Chem Phys 1961, V34, P809 HCA
- (19) Wildenburg, J; US 5230873 HCA
- L66 ANSWER 5 OF 15 HCA COPYRIGHT 2009 ACS on STN
- 128:40127 Original Reference No. 128:7771a,7774a In-situ investigations of the reversible hBN-cBN-hBN
  -transformation in the Li3N-BN catalyst system using synchrotron radiation. von der Gonna, J.; Meurer, H. J.; Nover, G.; Peun, T.; Schonbohm, D.; Will, G. (Poppelsdorfer Schloss, Mineralogisches Institut der Universitat Bonn, Bonn, Germany).
  Materials Letters, 33(5,6), 321-326 (English) 1998.
- CODEN: MLETDJ. ISSN: 0167-577X. Publisher: Elsevier Science B.V.. AB The kinetics of the transformation of **boron**
- nitride's hexagonal form (hBN) into the polymorphic cubic high pressure phase (cBN) were studied in the Li3N-BN catalyst system under in-situ pressure and temp. conditions. Energy-dispersive X-ray expts. were performed in a MAX 80 high pressure cell at HASYLAB, DESY, Hamburg using synchrotron radiation. The transformation of hBN into cBN and the reverse transformation of cBN into hBN within the same exptl. run were examd.

Simultaneously the kinetics of the transformation were detd. in the pressure range 0.65-6.5 GPa and at temps. between 600-1400°C.

It could be shown that, in most cases, the transformation was rather fast and it was completed in less than 5 min. The obsd. data

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confirm the exptl. results and the phase diagram as given by Bundy
     and Wentorf, but are in contrast to the exptl. results and thermodn.
     calcns. by Solozhenko and by Maki.
     10043-11-5, Boron nitride(bn), uses 26134-62-3,
ΙT
     Lithium nitride(Li3N)
        (in-situ investigations of reversible hBN-cBN
        -hBN-transformation in Li3N-BN catalyst
        system using synchrotron radiation)
     10043-11-5 HCA
RN
     Boron nitride (BN) (CA INDEX NAME)
CN
B \equiv N
     26134-62-3 HCA
RN
     Lithium nitride (Li3N) (CA INDEX NAME)
CN
   Li
Li-N-Li
CC
     67-3 (Catalysis, Reaction Kinetics, and Inorganic Reaction
     Mechanisms)
     Section cross-reference(s): 71
     boron nitride structural phase transition;
ST
     catalyst lithium nitride boron nitride; synchrotron
     radiation study boron nitride phase
ΙT
     Catalysts
     Physical process kinetics
     Structural phase transition
        (in-situ investigations of reversible hBN-cBN
        -hBN-transformation in Li3N-BN catalyst
        system using synchrotron radiation)
IT
     10043-11-5, Boron nitride(bn), uses 26134-62-3,
     Lithium nitride(Li3N)
        (in-situ investigations of reversible hBN-cBN
        -hBN-transformation in Li3N-BN catalyst
        system using synchrotron radiation)
L66 ANSWER 6 OF 15 HCA COPYRIGHT 2009 ACS on STN
126:205751 Original Reference No. 126:39655a Manufacture of
     cubic boron nitride from
     hexagonal one. Shioi, Tsunesuke; Masuda, Tomoyuki; Nakano,
     Hidefumi (Showa Denko Kk, Japan). Jpn. Kokai Tokkyo Koho JP 09000910 A 19970107 Heisei, 6 pp. (Japanese). CODEN:
     JKXXAF. APPLICATION: JP 1995-144382 19950612.
     The title method comprises conversion of hexagonal
AΒ
```

```
BN to cubic in the presence of (A) \geq 1
     selected from amide and imides of alkali metals and alk.-earth
     metals, (B) ≥1 selected from hydrides of alkali metals and
     alk.-earth metals, and optionally (C) \geq 1 selected from alkali
     metals and alk.-earth metals under keeping the temp. and pressure in
     the stable region for cubic BN. The method
     gives cubic BN with sharp edges under milder
     condition to be useful for whetstones.
     7439-93-2, Lithium, uses 7439-95-4, Magnesium,
ΙT
     uses 7580-67-8, Lithium hydride 7693-27-8,
     Magnesium hydride 7782-89-0, Lithium amide
     7803-54-5, Magnesium amide (Mg(NH2)2) 12135-01-2,
     Lithium imide
        (manuf. of cubic boron nitride from
        hexagonal one)
     7439-93-2 HCA.
RN
     Lithium (CA INDEX NAME)
CN
Li
     7439-95-4 HCA
RN
CN
     Magnesium (CA INDEX NAME)
Mg
RN
     7580-67-8 HCA
     Lithium hydride (LiH) (CA INDEX NAME)
CN
LiH
     7693-27-8 HCA
RN
     Magnesium hydride (MgH2) (CA INDEX NAME)
CN
MgH<sub>2</sub>
RN
     7782-89-0
                HCA
CN
     Lithium amide (Li(NH2)) (CA INDEX NAME)
Li-NH2
RN
     7803-54-5 HCA
CN
     Magnesium amide (Mg(NH2)2) (7CI, 8CI, 9CI) (CA INDEX NAME)
```

```
H_2N-Mg-NH_2
RN
     12135-01-2 HCA
    Lithium imide (Li2(NH)) (9CI) (CA INDEX NAME)
CN
Li-NH-Li
     10043-11-5, Boron nitride, processes
ΙT
        (manuf. of cubic boron nitride from
      hexagonal one)
     10043-11-5 HCA
RN
     Boron nitride (BN) (CA INDEX NAME)
CN
B \equiv N
TC
     ICM B01J003-06
     75-1 (Crystallography and Liquid Crystals)
CC
    boron nitride hexagonal cubic
ST
     conversion; crystal phase transition boron
     nitride; alkali metal amide cubic boron
     nitride; imide alk earth cubic boron
     nitride
ΙT
     Crystallization
     Structural phase transition
        (manuf. of cubic boron nitride from
        hexagonal one)
ΙT
     Abrasives
        (whetstones; manuf. of cubic boron
        nitride from hexagonal one)
     7439-93-2, Lithium, uses 7439-95-4, Magnesium,
IΤ
           7440-70-2, Calcium, uses 7580-67-8, Lithium hydride
     7693-27-8, Magnesium hydride 7782-89-0, Lithium
            7782-92-5, Sodium amide 7789-78-8, Calcium hydride
     7803-54-5, Magnesium amide (Mg(NH2)2) 12135-01-2,
                    12400-28-1, Calcium imide 17242-52-3, Potassium
     Lithium imide
             23321-74-6, Calcium amide 88676-47-5, Sodium imide
     amide
                187810-78-2, Lithium imide (K2(NH))
        (manuf. of cubic boron nitride from
        hexagonal one)
IT
     10043-11-5, Boron nitride, processes
        (manuf. of cubic boron nitride from
        hexagonal one)
```

L66 ANSWER 7 OF 15 HCA COPYRIGHT 2009 ACS on STN

126:150690 Original Reference No. 126:29029a Kinetic features of

```
crystallization of cubic boron nitride
     single crystals in the BN-LiH(N,Se) system. Gameza, L. M.; Shipilo,
     V. B.; Savchuk, V. A. (Institut Solid State Semiconductor Physics,
     Minsk, 220726, Belarus). Physica Status Solidi B: Basic Research,
     198(1), 559-563 (English) 1996. CODEN: PSSBBD.
     0370-1972.
                 Publisher: Akademie Verlag.
     The effect of Se addns. on the kinetics of the degree and rate of
AΒ
     hexagonal to cubic BN conversion (
     hBN \rightarrow cBN) as well as on the linear rate of
     the cBN crystal growth in the BN-LiH(N,Se) system was
     investigated. Expts. were performed at 1940-2080 K and 4.3 GPa.
     For 0.5, 1.0, and 3.0 % Se addn., the activation energy of the
     process of cBN formation is 45.0, 39.0, and 34.0 kJ/mol,
     resp. The resulting crystals showed n-type conduction with a
     resistivity of 105-108 \Omega cm and a dislocation d. of 105-103
     cm-2.
     7580-67-8, Lithium hydride
ΙT
        (catalyst for crystal growth of cubic
        boron nitride and phase
        transition of hexagonal BN -
        cubic BN in BN-LiH(N,Se) system)
     7580-67-8
RN
               HCA
     Lithium hydride (LiH) (CA INDEX NAME)
CN
LiH
IT
     10043-11-5, Boron nitride, properties
        (crystal growth kinetics of cubic boron
        nitride and phase transition kinetics
        of hexagonal BN - cubic
        BN in BN-LiH(N,Se) system)
     10043-11-5 HCA
RN
     Boron nitride (BN) (CA INDEX NAME)
CN
B \equiv N
     75-1 (Crystallography and Liquid Crystals)
CC
     Section cross-reference(s): 76
     crystal growth kinetics cubic boron
ST
     nitride; selenium phase transition
     kinetics boron nitride; resistance dislocation density cubic
    boron nitride
IT
     Electric resistance
        (of cubic boron nitride crystals
        obtained from crystal growth and hexagonal BN
        → cubic BN phase
```

```
transition in BN-LiH(N,Se) system)
    Activation energy
ΙT
        (of cubic boron nitride formation
        in presence of selenium)
IT
    Crystal growth kinetics
        (of cubic boron nitride in
        BN-LiH(N,Se) system)
    Structural phase transition
ΙT
        (of hexagonal boron nitride
        → cubic boron nitride in
        BN-LiH(N,Se) system)
     7580-67-8, Lithium hydride
IT
        (catalyst for crystal growth of cubic
       boron nitride and phase
        transition of hexagonal BN ->
       cubic BN in BN-LiH(N,Se) system)
     10043-11-5, Boron nitride, properties
IT
        (crystal growth kinetics of cubic boron
       nitride and phase transition kinetics
       of hexagonal BN - cubic
       BN in BN-LiH(N,Se) system)
     7782-49-2, Selenium, processes
IT
        (effect on crystal growth kinetics of cubic
       boron nitride and phase
        transition kinetics of hexagonal BN
       → cubic BN in BN-LiH(N,Se)
        system)
    ANSWER 8 OF 15 HCA COPYRIGHT 2009 ACS on STN
L66
124:350220 Original Reference No. 124:64889a,64892a Growth mechanism of
     CBN crystals under high pressure and high temperature.
     Zhou, Yanping; Yan, Xuewei; Ma, Xianfeng; Zhao, Tinghe (Changchun
     Inst. of Applied Chem., Chinese Academy of Sci., Changchun, 130022,
     Peop. Rep. China). Wuji Cailiao Xuebao, 10(4), 391-8 (Chinese)
     1995. CODEN: WCXUET. ISSN: 1000-324X. Publisher: Kexue.
     Cubic boron nitride was synthesized
AB
     under the conditions of high pressure (4.5-5.0 GPa) and the high
     temp. of 1500-1800°C. Two types of cubic (
     c) BN, synthesized in the Li-complex nitride or
     boride-nitride catalytic systems and in the same
     catalytic system with additive complex nitride Li8SiN4, were
     compared. The surface structure and growth mechanism of CBN
     crystals were discussed.
                               The behavior of Si in the phase
     transformation from hexagonal (h)
     BN to cBN was studied. When complex nitride
     Li8SiN4 was added to the catalytic system, its partial
     dissoln. increased the satn. degree and the viscosity of melt, which
     increased crystal boundary energy and decreased nucleation rate.
```

```
The glossy transparent cBN crystals having brown luster
     were synthesized.
IT
     10043-11-5P, Boron nitride, preparation
        (cubic; effects of Li8SiN4 additive on the growth
       mechanism of cubic BN crystals from
       hexagonal BN under high pressure and high
        temp.)
     10043-11-5 HCA
RN
     Boron nitride (BN) (CA INDEX NAME)
CN
B \equiv N
ΙT
     12521-66-3, Lithium silicon nitride (Li8SiN4)
        (effects of Li8SiN4 additive on the growth mechanism of
        cubic BN crystals from hexagonal
       BN under high pressure and high temp.)
     12521-66-3 HCA
ŔN
     Silanetetramine, octalithium salt (9CI) (CA INDEX NAME)
CN
     NH2
H2N-Si-NH2
     NH2
  ●8 Li
CC
     57-2 (Ceramics)
ST
     cubic boron nitride crystal growth
     mechanism
     10043-11-5P, Boron nitride, preparation
ΙT
        (cubic; effects of Li8SiN4 additive on the growth
       mechanism of cubic BN crystals from
       hexagonal BN under high pressure and high
        temp.)
     12521-66-3, Lithium silicon nitride (Li8SiN4)
IT
        (effects of Li8SiN4 additive on the growth mechanism of
        cubic BN crystals from hexagonal
       BN under high pressure and high temp.)
L66 ANSWER 9 OF 15 HCA COPYRIGHT 2009 ACS on STN
124:13785 Original Reference No. 124:2653a,2656a Modification of
     mechanical properties of nitrogen-sputtered boron nitride films by
     ion bombardment. Jensen, H.; Jensen, U. M.; Sorensen, G. (Inst.
```

Phys. Astronomy, Aarhus Univ., Aarhus, 8000-DK, Den.). Surface and Coatings Technology, 74-75(1-3, Pt. 2), 781-7 (English) 1995 CODEN: SCTEEJ. ISSN: 0257-8972. Publisher: Elsevier. Boron nitride is a fascinating coating material, both in the AΒ electronics industry and for tribol. applications. For the various applications the cryst. structure is important, and there is a need for studies of its basic nature and of its surface modification by A large variety of high temp. processes for prodn. of ion beams. boron nitride exists, whereas there are only a few reports on low temp. processes, such as reactive r.f. sputtering. In these cases, only boron nitride targets have been used and usually in argon-nitrogen sputtering mixts. The authors of the present paper have, however, shown that boron nitride can be deposited by a reactive nitrogen-sputtering process from a boron metal target without argon at all. The acoustic scratch test technique was used as a kind of mech. test for nitrogen-sputtered BN deposited on cemented carbide. The effect of a neg. substrate bias and sputter gas mixts. of nitrogen and krypton was studied. Although nitrogen-krypton sputter gas mixts. had only a marginal effect on sputter rates, they had a significant effect on the mech. film A post-ion bombardment of nitrogen-sputtered BN properties. coatings with nitrogen ions in the hundreds of kiloelectronvolts range was also effective for modification of the mech. properties. The possibility of ion implanting a lithium catalyst for a cryst. transformation from hexagonal to cubic cryst. structure was discussed, and lithium ion implantation did show a modification of surface friction properties. This novel process of nitrogen sputtering of boron may improve understanding of the fundamental aspects of phase control in the deposition of boron nitride films.

IT 7439-93-2, Lithium, processes

(catalyst, implantation ion; effects of lithium implantation hexagonal to cubic phase

transformation and friction properties of boron nitride coatings prepd. by reactive nitrogen sputtering from boron targets)

RN 7439-93-2 HCA

CN Lithium (CA INDEX NAME)

Li

IT 10043-11-5, Boron nitride, processes

(coatings; effects of ion bombardment on mech. properties of boron nitride coatings prepd. by reactive nitrogen sputtering from boron targets)

RN 10043-11-5 HCA

CN Boron nitride (BN) (CA INDEX NAME)

```
B \equiv N
```

CC 57-2 (Ceramics)

IT Friction

(effects of lithium implantation hexagonal to

cubic phase transformation and

friction properties of boron nitride coatings prepd. by reactive nitrogen sputtering from boron targets)

IT 7439-93-2, Lithium, processes

(catalyst, implantation ion; effects of lithium

implantation hexagonal to cubic phase

transformation and friction properties of boron nitride coatings prepd. by reactive nitrogen sputtering from boron targets)

IT 10043-11-5, Boron nitride, processes

(coatings; effects of ion bombardment on mech. properties of boron nitride coatings prepd. by reactive nitrogen sputtering from boron targets)

L66 ANSWER 10 OF 15 HCA COPYRIGHT 2009 ACS on STN

122:110152 Original Reference No. 122:20631a,20634a phase

-transfer process and catalysts for cubic

boron nitride formation from hexagonal

boron nitride. Shioi, Kousuke; Nakano, Hidefumi

(Showa Denko K. K., Japan). Ger. Offen. DE 4423987 A1

**19950112**, 7 pp. (German). CODEN: GWXXBX. APPLICATION: DE 1994-4423987 19940707. PRIORITY: JP 1993-170537 19930709; JP

1994-19508 19940216.

AB The process comprises subjecting hexagonal BN (

hBN) to hot pressing at a temp. and pressure in the range where cubic BN (cBN) is stable, and in

the presence of ≥1 compds. selected from the amide and imide of Group IA and IIA elements. Residual hexagonal

BN is removed with NaOH. A mixt. of hBN and Li

amide in Li/B at. ratio 20:100 was compression-molded and the material was heat-treated at 4.5 GPa and 1400° for 10 min to give cBN at a conversion rate of 84%.

IT 10043-11-5P, Boron nitride (BN), preparation

(phase-transfer process and catalysts for

cubic boron nitride formation from

hexagonal boron nitride)

RN 10043-11-5 HCA

CN Boron nitride (BN) (CA INDEX NAME)

```
7439-93-2, Lithium, uses 7439-95-4, Magnesium,
IT
    uses 7782-89-0, Lithium amide
        (phase-transfer process and catalysts for
        cubic boron nitride formation from
       hexagonal boron nitride)
     7439-93-2 HCA
RN
CN
    Lithium (CA INDEX NAME)
Li
RN
     7439-95-4 HCA
    .Magnesium (CA INDEX NAME)
CN
Mq
     7782-89-0 HCA
RN
     Lithium amide (Li(NH2)) (CA INDEX NAME)
CN
Li-NH2
IC
     ICM C01B021-064
     ICS C30B029-38; C30B028-02
     C09K003-14
ICA
     49-5 (Industrial Inorganic Chemicals)
CC
     Section cross-reference(s): 57
     boron nitride hexagonal cubic
ST
     phase transfer; lithium amide phase transfer
     catalyst; Group IA IIA amide imide catalyst;
     magnesium phase transfer catalyst; calcium
     phase transfer catalyst; chromium phase
     transfer catalyst; manganese phase transfer
     catalyst; iron phase transfer catalyst;
     cobalt phase transfer catalyst; nickel
     phase transfer catalyst; zinc phase
     transfer catalyst; aluminum phase transfer
     catalyst; lanthanum phase transfer
     catalyst; cerium phase transfer catalyst
     ; praseodymium phase transfer catalyst;
     neodymium phase transfer catalyst; samarium
     phase transfer catalyst; gadolinium phase
     transfer catalyst
     Alkali metals, uses
IT
     Alkaline earth metals
     Group IIB elements
```

```
Group IIIA elements
     Group IIIB elements
     Group VIB elements
     Group VIIB elements
     Group VIII elements
        (phase-transfer process and catalysts for
        cubic boron nitride formation from
        hexagonal boron nitride)
     Alkali metal compounds
IT
     Alkaline earth compounds
        (amides, phase-transfer process and catalysts
        for cubic boron nitride formation
        from hexagonal boron nitride)
ΙT
     Powder metallurgy
        (hot-pressing, phase-transfer process and
        catalysts for cubic boron
        nitride formation from hexagonal boron
        nitride)
     Alkali metal compounds
ΙT
     Alkaline earth compounds
        (imides, phase-transfer process and catalysts
        for cubic boron nitride formation
        from hexagonal boron nitride)
     Catalysts and Catalysis
IT
        (phase-transfer, phase-transfer process and
        catalysts for cubic boron
        nitride formation from hexagonal boron
        nitride)
     1310-73-2, Sodium hydroxide, uses
IT
        (leachant; phase-transfer process and catalysts
        for cubic boron nitride formation
        from hexagonal boron nitride)
     10043-11-5P, Boron nitride (BN), preparation
IT
        (phase-transfer process and catalysts for
        cubic boron nitride formation from
        hexagonal boron nitride)
                                7439-89-6, Iron, uses
                                                         7439-91-0,
     7429-90-5, Aluminum, uses
IT
     Lanthanum, uses 7439-93-2, Lithium, uses 7439-95-4
      Magnesium, uses 7439-96-5, Manganese, uses
                                                      7440-00-8,
     Neodymium, uses 7440-02-0, Nickel, uses 7440-10-0, Praseodymium,
           7440-19-9, Samarium, uses 7440-42-8, Boron, uses
     7440-45-1, Cerium, uses 7440-47-3, Chromium, uses 7440-48-4,
                   7440-54-2, Gadolinium, uses
                                                 7440-66-6, Zinc, uses
     Cobalt, uses
     7440-70-2, Calcium, uses 7782-89-0, Lithium amide
        (phase-transfer process and catalysts for
        cubic boron nitride formation from
        hexagonal boron nitride)
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(1) Anon; DE 1220837 B
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(2) Anon; DE 2829383 A1 HCA

(3) Anon; US 2947617 A HCA

(4) Anon; DD 89395 C

L66 ANSWER 11 OF 15 HCA COPYRIGHT 2009 ACS on STN

118:32031 Original Reference No. 118:5661a,5664a Effect of several additives in the synthesis of **cubic boron**nitride using alkali or alkaline earth nitrides.

Bocquillon, Genevieve; Loriers-Susse, Christiane; Loriers, Jean (Lab. Physicochim. Mater., Meudon, 92195, Fr.). Comptes Rendus

(Lab. Physicochim. Mater., Meudon, 92195, Fr.). Comptes Rendus de l'Academie des Sciences, Serie II: Mecanique, Physique, Chimie, Sciences de la Terre et de l'Univers, 315(9), 1069-72 (French) 1992. CODEN: CRAMED. ISSN: 0764-4450.

AB Addn. in appropriate proportion of particular elements M' such as Al, B, Si, Ti to hexagonal BN and alk. or alk.
earth nitrides MxNy, more precisely to Li3N, Ca3N2, Mg3N2, leads in fluxes at high pressure to cubic BN crystals
with smoother faces, sharper edges and more compact shapes, these characteristics allowing one to foresee their higher strength. This addn. increases the crystal size which reaches 0.5 mm. This effect is interpreted as resulting from flux modifications, 1 of which is the apparition of excess B. One observes a correlation between the proportion of M' corresponding to the complete redn. of MxNy by M' and the min. proportion giving a majority of crystals showing the new morphol. The latter is accompanied by a color change from yellow-orange to brown-black.

IT 26134-62-3, Lithium nitride 56127-34-5, Magnesium nitride

(for prepn. of cubic boron nitride by high-pressure phase transition in fluxes)

RN 26134-62-3 HCA

CN Lithium nitride (Li3N) (CA INDEX NAME)

Li Li-N-Li

RN 56127-34-5 HCA

CN Magnesium nitride (CA INDEX NAME)

Component	 	Ratio	1	Component Registry Number
=========	=+=		+=	===============
N	1	x	1	17778-88-0
Mg	1	x	1	7439-95-4

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LANGEL 10/568,438
     10043-11-5P, Boron nitride (BN), preparation
        (prepn. of cubic, by high-pressure phase
        transition in fluxes contq. alkali metal or alk. earth
        nitrides and various elements)
     10043-11-5 HCA
RN
     Boron nitride (BN) (CA INDEX NAME)
CN
B \equiv N
     78-5 (Inorganic Chemicals and Reactions)
CC
     Section cross-reference(s): 57
     boron nitride cubic prepn additive;
ST
     crystal form improvement cubic boron
     nitride
     Crystal morphology
IT
        (of boron nitride prepd. by high-pressure phase
        transition in fluxes contg. various elements and alkali
       metal or alk. earth nitrides)
                                                            7440-32-6,
     7429-90-5, Aluminum, uses 7440-21-3, Silicon, uses
IT
     Titanium, uses 7440-42-8, Boron, uses 12013-82-0, Calcium
     nitride 26134-62-3, Lithium nitride 56127-34-5,
     Magnesium nitride
        (for prepn. of cubic boron nitride
        by high-pressure phase transition in fluxes)
     10043-11-5P, Boron nitride (BN), preparation
IT
        (prepn. of cubic, by high-pressure phase
        transition in fluxes contg. alkali metal or alk. earth
        nitrides and various elements)
L66 ANSWER 12 OF 15 HCA COPYRIGHT 2009 ACS on STN
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L66 ANSWER 12 OF 15 HCA COPYRIGHT 2009 ACS on STN
115:259338 Original Reference No. 115:44061a,44064a Preparation of mixtures for cubic boron nitride
manufacture. Matus, Eduard (Czech.). Czech. CS 269746 B1
19910206, 4 pp. (Czech). CODEN: CZXXA9. APPLICATION: CS
1989-1845 19890324.

AB The process comprises hot pressing powd. mixts. consisting 10-90 wt.% hexagonal BN and balance catalyst at 600-1000° to obtain mixts. having d. >65% of theor. The catalyst is selected from Li3BN2, LiMgBN2, and LiCaBN2.

IT 12408-97-8, Boron lithium nitride (BLi3N2) 87354-58-3 137635-80-4

(catalyst, phase transfer, mixts. contg. hexagonal boron nitride and, prepn.

of powd., for cubic boron nitride manuf.)

RN 12408-97-8 HCA

CN Boranamine, 1-imino-, trilithium salt (9CI) (CA INDEX NAME)

 $H_2N-B=NH$ 

●3 Li

RN 87354-58-3 HCA CN Boranamine, 1-imino-, calcium lithium salt (1:1:1) (9CI) (CA INDEX NAME)

 $H_2N-B=NH$ 

● Ca

● Li

RN 137635-80-4 HCA
CN Boranamine, 1-imino-, lithium magnesium salt (1:1:1) (9CI) (CA
INDEX NAME)

 $H_2N-B=NH$ 

● Li

Mg

```
B \equiv N
     ICM C01B021-064 ·
IC
CC
     49-5 (Industrial Inorganic Chemicals)
     hexagonal boron nitride hot pressing;
ST
     phase transfer catalyst hot pressing;
     cubic boron nitride manuf
     hexagonal; lithium boron nitride catalyst;
     magnesium lithium boron nitride; calcium lithium boron nitride
IT
        (hot pressing, densification by, of hexagonal
        boron nitride-phase transfer
        catalyst mixts., in cubic boron
        nitride manuf.)
     12408-97-8, Boron lithium nitride (BLi3N2)
ΙT
     87354-58-3 137635-80-4
        (catalyst, phase transfer, mixts. contg.
        hexagonal boron nitride and, prepn.
        of powd., for cubic boron nitride
        manuf.)
     10043-11-5P, Boron nitride, preparation
ΙT
        (cubic, manuf. of, from hexagonal
        boron nitride, phase transfer
        catalyst-contg. mixt. prepn. for, by hot pressing)
    ANSWER 13 OF 15 HCA COPYRIGHT 2009 ACS on STN
101:115742 Original Reference No. 101:17605a,17608a
     boron nitrides. (Showa Denko K. K., Japan).
     Kokai Tokkyo Koho JP 59073411 A 19840425 Showa, 5 pp.
     (Japanese). CODEN: JKXXAF. APPLICATION: JP 1982-180007 19821015.
     In the catalytic synthesis of cubic BN
AB
     from hexagonal BN, the catalyst is
    prepd. from a (1-1.4):(1-1.4):3 mol ratio mixt. of Li3N, at least 2
     nitrides of Be, Mg, Ca, Sr, and Ba, and BN by calcining in an inert
     atm. at 700-1200°. Thus, a mixt. contg. Li3N, Mg3N2, Sr3N2,
     and BN in 1:0.9:0.4:3 mol ratio was fired at 1000° for 1 h in
     N2, crushed to <150 mesh, mixed with hexagonal BN
     at a 1:5 wt. ratio, molded, and hot-pressed at 1450^{\circ} and 53
     kbar for 10 min to give cubic BN in 43% yield,
     compared to 28 when the catalyst mixt. was not fired.
     12057-71-5 26134-62-3
IT
        (catalysts, for hexagonal-to-cubic
        boron nitride phase
        transformation, firing of, for increased cubic
        phase yield)
     12057-71-5 HCA
RN
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Magnesium nitride (Mg3N2) (CA INDEX NAME)
*** STRUCTURE DIAGRAM IS NOT AVAILABLE ***
RN
     26134-62-3 HCA
     Lithium nitride (Li3N) (CA INDEX NAME)
CN
   Li
Li-N-Li
     10043-11-5, properties
IT
        (hexagonal-to-cubic phase
        transformation of, nitride catalysts for,
        firing of, for increased cubic phase yield)
     10043-11-5 HCA
RN
     Boron nitride (BN) (CA INDEX NAME)
CN
B \equiv N
     C01B021-064; B01J027-24
IC
CC
     57-2 (Ceramics)
ST
     cubic boron nitride prepn
     Catalysts and Catalysis
ΙT
        (nitride, for hexagonal-to-cubic
       boron nitride transformation, firing of, for
        increased cubic phase yield)
     12033-82-8 12057-71-5 26134-62-3
ΤT
        (catalysts, for hexagonal-to-cubic
       boron nitride phase
        transformation, firing of, for increased cubic
        phase yield)
     10043-11-5, properties
IT
        (hexagonal-to-cubic phase
        transformation of, nitride catalysts for,
        firing of, for increased cubic phase yield)
     ANSWER 14 OF 15 HCA COPYRIGHT 2009 ACS on STN
101:115737 Original Reference No. 101:17601a,17604a
                                                       Cubic
     boron nitride. (Showa Denko K. K., Japan).
     Kokai Tokkyo Koho JP 59057905 A 19840403 Showa, 4 pp.
     (Japanese). CODEN: JKXXAF. APPLICATION: JP 1982-168269 19820929.
     A (1-1.4):(1-1.4):3 mixt. of Li3N, Mg3N2, Sr3N2, or Be3N2, and BN is
AΒ
     heated at 800-1300° in an inert gas atm., powd., and used at
     catalyst. A compacted mixt. of the catalyst and
     hexagonal BN (h-BN) has higher
     strength than a conventional mixt. of h-BN and
     Li3BN2 or Ca3B2N4 so that the heating period at a high temp. and
```

```
pressure is shorter with higher yield of cubic BN
        Thus, a 1:1:3 mixt. of Li3N, Mg3N2, and BN -150 mesh each was
     heated in a Pt crucible in a N2 stream 8 L/min at 900° for 1
     h, powd. to <150 mesh in N2, mixed with h-8N in a 1:3 ratio,
     compacted to 20 diam. + 20 mm, and heated at 60 kbar and
     1500^{\circ} for 10 min. The strength (X 108 kg/m2) was 4.25 and
     cubic BN yield 38%, compared to 3.50 and 18,
     resp., when a 1.1:1.2:3 mixt. was compacted and heated directly, or
     3.64 and 26, resp. when a 1:3 mixt. of Li3BN2 and h-
     BN was compacted and heated at 56 kbar and 1450° for
     20 min.
     12057-71-5 26134-62-3
IT
        (catalyst contg., for hexagonal-to-
        cubic boron nitride transformation,
        filing of, for increased yield of cubic phase
     12057-71-5 HCA
RN
     Magnesium nitride (Mg3N2) (CA INDEX NAME)
CN
    STRUCTURE DIAGRAM IS NOT AVAILABLE ***
     26134-62-3 HCA
RN
     Lithium nitride (Li3N) (CA INDEX NAME)
CN
  Li
Li-N-Li
     10043-11-5, properties
IT
        (hexagonal-to-cubic phase
        transformation of, nitride catalysts for,
        filing of, for increased cubic phase yield)
     10043-11-5 HCA
RN
                         (CA INDEX NAME)
CN
     Boron nitride (BN)
B \equiv N
     C01B021-064; B01J027-24
IC
CC
     57-2 (Ceramics)
ST
     cubic boron nitride prepn
     Catalysts and Catalysis
IT
        (nitride, for boron nitride hexagonal
        -to-cubic phase transformation,
        filing of, for increased cubic phase yield)
     1304-54-7 12033-82-8 12057-71-5 26134-62-3
IT
        (catalyst contg., for hexagonal-to-
        cubic boron nitride transformation,
        filing of, for increased yield of cubic phase
```

```
10043-11-5, properties
ΙT
        (hexagonal-to-cubic phase
        transformation of, nitride catalysts for,
        filing of, for increased cubic phase yield)
```

L66 ANSWER 15 OF 15 HCA COPYRIGHT 2009 ACS on STN 92:224514 Original Reference No. 92:36203a,36206a Formation of cubic boron nitride by using calcium oxide and lithium nitride as catalysts. Hasegawa, Kanemitsu; Sekiya, Tadashi; Nakayama, Noboru (Gov. Ind. Res. Inst., Nagoya, Nagoya, Japan). Nagoya Kogyo Gijutsu Shikensho Hokoku, 28(12), 388-93 (Japanese) **1979**. CODEN: NKGSAR. 0027-7614.

The effect of CaO and Li3N as catalyst on the transition of hexagonal BN into cubic BN was investigated. One part (by wt.) of CaO or Li3N was mixed with 4 or 3 parts of hexagonal BN, and each mixt. was kept for 15-20 min at  $800-1600^{\circ}$  and 5-7 GPa. X-ray diffraction anal. showed for CaO that those species assocd. with processed samples are cubic BN,

hexagonal BN, Ca3B2O6, and CaO and that the higher the pressure or temp., the more rapidly cubic BN is produced. CaO may be regarded as a good catalyst; the temp.-pressure condition may be made milder if the crystallinity of hexagonal BN has been increased by heating it in vacuo for 3 h at 600°. Li3N is far superior to CaO in catalytic activity, which is almost independent of the crystallinity of hexagonal BN.

26134-62-3 IT

> (catalysis by, of boron nitride hexagonal-cubic phase transition)

26134-62-3 HCA RN

CN Lithium nitride (Li3N) (CA INDEX NAME)

Li Li-N-Li

AB

IT **10043-11-5**, properties (phase transitions of, effect of calcium oxide and lithium nitride on hexagonal-cubic) 10043-11-5 RN HCA

CN Boron nitride (BN) (CA INDEX NAME)

## $B \equiv N$

- CC 75-3 (Crystallization and Crystal Structure) Section cross-reference(s): 67
- ST boron nitride cubic formation catalyst; phase transition boron nitride catalyst; calcium oxide transition boron nitride; lithium nitride boron phase transition
- IT Catalysts and Catalysis
  (calcium oxide and lithium nitride, for boron
  nitride hexagonal-cubic phase
  transition)

## => D L67 1-30 CBIB ABS HITSTR HITIND RE

- L67 ANSWER 1 OF 30 HCA COPYRIGHT 2009 ACS on STN
  142:413422 High temperature and high pressure method for synthesizing B-C-N cubic crystal in the presence of catalyst.

  Tian, Yongjun (Yanshan University, Peop. Rep. China). Faming Zhuanli Shenqing Gongkai Shuomingshu CN 1451472 A 20031029, 5 pp. (Chinese). CODEN: CNXXEV. APPLICATION: CN 2003-128765 20030509.
- BN based on BxCy(BN)z, mech. alloying in vacuum or in protective gas ambient for 50-200 h to obtain precursor; press forming with catalyst powder (Ca3B2N4, Mg3B2N4, Li3N, Ca3N2, or Mg3N2), assembling with graphite (Ta, NaCl, or ZrO2)-lined tubular, pyrophyllite tubular, or graphite tubular heater, synthesizing at ≥1100° and ≥5 GPa for 2-30 min, and treating in H2SO4-HNO3 to dissolve and remove catalyst. The BC2N and B2CN hexagonal crystals are synthesized by the method.
- RN 10043-11-5 HCA
- CN Boron nitride (BN) (CA INDEX NAME)

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B \!\! \equiv \!\! \! = \!\! \! N
```

RN 12057-71-5 HCA
CN Magnesium nitride (Mg3N2) (CA INDEX NAME)
\*\*\* STRUCTURE DIAGRAM IS NOT AVAILABLE \*\*\*
RN 26134-62-3 HCA
CN Lithium nitride (Li3N) (CA INDEX NAME)

Li
Li
N-Li

4.

IC ICM B01J003-06
CC 47-4 (Apparatus and Plant Equipment)
Section cross-reference(s): 67

ST boron carbon nitride hexagonal crystal synthesis

IT Catalysts

(high temp. and high pressure method for synthesizing B-C-N cubic crystal in presence of catalyst)

IT 120039-00-1P, Boron carbide nitride (BC2N) 730241-98-2P, Boron carbide nitride (B2CN)

(high temp. and high pressure method for synthesizing B-C-N cubic crystal in presence of catalyst)

1314-23-4, Zirconia, uses 7440-25-7, Tantalum, uses 7440-42-8 Boron, uses 7647-14-5, Sodium chloride, uses 7782-42-5, Graphite, uses 10043-11-5, Boron nitride, uses 12013-82-0, Calcium nitride 12057-71-5, Magnesium nitride 26134-62-3, Lithium nitride 65453-51-2 71330-55-7 (high temp. and high pressure method for synthesizing B-C-N cubic crystal in presence of catalyst)

L67 ANSWER 2 OF 30 HCA COPYRIGHT 2009 ACS on STN
139:106982 Study on the **catalytic** function of **Li3N**,

Mg3N2, Ca3N2. Xu, Xiao-Wei; Li, Yu-Ping; Zhao, Hong-Mei;
Fan, Hui-Li; Zhang, Yong-Jie (Material Science and Engineering School, University of Science and Technology Beijing, Beijing,

100083, Peop. Rep. China). Gaoya Wuli Xuebao, 17(2), 141-144 (Chinese) 2003. CODEN: GWXUER. ISSN: 1000-5773.

Publisher: Gaoya Wuli Xuebao Bianjibu.

AB T is well known that Li3N, Mg3N2 and Ca3N2 are catalysts for cBN synthesis under high temp. and high pressure. We discovered that they could also act as catalysts for hBN formation at high temp. and normal pressure. It is confirmed that, from a series comparative expts., each of them has catalysts effect only on melting

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condition, the catalytic order for hBN formation
     is Li3N > Mg3N2 > Ca3N2, which is similar to
     that for cBN synthesis. The suggestion that a
     catalyst for hBN formation may also be a
     catalyst for cBN synthesis may be reliable.
     12057-71-5, Magnesium nitride(mg3n2)
IT
     26134-62-3, Lithium nitride(li3n)
        (catalytic function of Li3N, Mg3N2,
        Ca3N2)
     12057-71-5
                HCA
RN
     Magnesium nitride (Mg3N2) (CA INDEX NAME)
CN
*** STRUCTURE DIAGRAM IS NOT AVAILABLE ***
     26134-62-3 HCA
RN
     Lithium nitride (Li3N) (CA INDEX NAME)
CN
   Li
Li-N-Li
     10043-11-5P, Boron nitride, preparation
TT
        (cubic and hexagonal; catalytic
        function of Li3N, Mg3N2, Ca3N2)
     10043-11-5 HCA
RN
     Boron nitride (BN) (CA INDEX NAME)
CN
B \equiv N
     67-1 (Catalysis, Reaction Kinetics, and Inorganic Reaction
CC
     Mechanisms)
     lithium nitride catalyst synthesis cubic
ST
     hexagonal boron nitride; magnesium
     nitride catalyst synthesis cubic
     hexagonal boron nitride; calcium nitride
     catalyst synthesis cubic hexagonal
     boron nitride
     Catalysts
        (catalytic function of Li3N, Mg3N2,
        Ca3N2)
     Nitrides
IΤ
        (catalytic function of Li3N, Mg3N2,
     12013-82-0, Calcium nitride(ca3n2) 12057-71-5, Magnesium
IT
     nitride(mq3n2) 26134-62-3, Lithium nitride(
        (catalytic function of Li3N, Mg3N2,
        Ca3N2)
```

- IT 10043-11-5P, Boron nitride, preparation (cubic and hexagonal; catalytic function of Li3N, Mg3N2, Ca3N2)
- L67 ANSWER 3 OF 30 HCA COPYRIGHT 2009 ACS on STN
  131:93072 Investigation of the chemical reactivity and stability of
  c-BNP. Sachdev, H.; Strauss, M. (Institute for Inorganic Chemistry
  FR 11.1, University of Saarland, Saarbruecken, 66041, Germany).
  Diamond and Related Materials, 8(2-5), 319-324 (English)
  1999. CODEN: DRMTE3. ISSN: 0925-9635. Publisher: Elsevier
  Science S.A..
- Bulk material of cubic boron nitride ( AΒ **c-BN**) is com. achieved via high pressure-high temp. (HPHT) synthesis from h-BN with various catalysts (flux precursors). Since recent investigations indicated c-BN to be the stable modification at std. conditions there is considerable interest to realize a **c-BN** synthesis at normal or low pressure. Thus growth conditions allowing high mobility for boron and nitrogen atoms have to be found. The interaction of c-BN with various flux precursors used under HPHT conditions was investigated up to 1300 °C at ambient pressure. The reagents were chosen with regard to their ability to stabilize intermediate reaction products. Metals, nitrides and fluorides were applied for the chem. attack. The morphol. changes and degrdn. of the  ${f c}$ -BN crystals were examd. by SEM, X-ray diffraction and IR spectroscopy. SEM studies indicate that the degrdn. of c-BN depends strongly on the nature of the flux precursors. Those leading to an intermediate phase during the reaction exhibit distinct etching figures on (111)-planes of c-BN, while reagents leading to the formation of several products cause an inhomogeneous decay. Since the degrdn. of c-BN resembles the reversed growth, the reaction mechanism of the interaction of c-BN with reactive melts allows to establish a growth and degrdn. model of the cubic phase. The results shall help finding new routes to grow c-BN in a low pressure-melt or chem. vapor deposition process.
- IT 12057-71-5, Magnesium nitride (mg3n2)

(investigation of chem. reactivity and stability of c-BNP)

- RN 12057-71-5 HCA
- CN Magnesium nitride (Mg3N2) (CA INDEX NAME)
- \*\*\* STRUCTURE DIAGRAM IS NOT AVAILABLE \*\*\*
- CC 67-3 (Catalysis, Reaction Kinetics, and Inorganic Reaction Mechanisms)
- ST chem reactivity stability cubic boron nitride
- IT 7429-90-5, Aluminum, reactions 7439-95-4, Magnesium, reactions

7440-43-9, Cadmium, reactions 7440-66-6, Zinc, reactions 7440-70-2, Calcium, reactions 7637-07-2, Boron trifluoride, reactions 7681-49-4, Sodium fluoride, reactions 7783-40-6, Magnesium fluoride(mgf2) 7783-49-5, Zinc difluoride 10043-11-5, Boron nitride, reactions 12057-71-5, Magnesium nitride(mg3n2)

(investigation of chem. reactivity and stability of c-BNP)

RE

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- L67 ANSWER 4 OF 30 HCA COPYRIGHT 2009 ACS on STN
- 127:286129 Original Reference No. 127:55731a,55734a Kinetic and thermodynamic investigation of **cBN** formation in the system BN-Mg3N2. Lorenz, H.; Peun, T.; Orgzall, I. (Fachbereich Physikalische Technik, Markische Fachhochschule, Iserlohn, D-58644, Germany). Applied Physics A: Materials Science & Processing, 65(4/5), 487-495 (English) 1997. CODEN: APAMFC. ISSN: 0947-8396. Publisher: Springer.
- AB Exptl. high pressure-high temp. results on **cBN** formation in the **Mg3N2**-BN system are presented and discussed. In particular, a temp. region slightly above the lower limit of the formation region characterized by fast transformation processes and submicron **cBN** grains strongly agglomerated was investigated in more detail concerning thermodn. and kinetics. The **catalyst**/solvent active in that temp. interval is Mg3BN3

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previously formed at ≈5.5 GPa and 1170 K in a solid-state
    reaction. The cBN formation proceeds as pptn. from a
     eutectic melt formed by the intermediate compd. and BN.
     results are used to improve the previously proposed phase
     diagram for the Mg3N2-BN system. The kinetics is
     discussed based on the usual Avrami theory.
                                                  It follows that the
     processes may be described by nearly instantaneous nucleation at the
     beginning of the reaction with large rate. Growth processes are
     soon inhibited due to strong impingement of the formed nuclei and
    grains so that an Avrami exponent n in the neighborhood of 1
     results. This exponent, as well as the rate const. k summarizing
     the phys. mechanisms of nucleation and growth, show a temp.
     dependence.
     10043-11-5, Boron nitride, properties
       (cubic; kinetics of c-BN formation
       due to structural transition in the system h-BN
        /Mq3N2)
     10043-11-5 HCA
     Boron nitride (BN) (CA INDEX NAME)
B \equiv N
     121768-76-1, Boron magnesium nitride (BMg3N3)
        (formation during c-BN formation due to
        structural transition in the system h-BN/
       Mg3N2)
     121768-76-1 HCA
     Boranetriamine, magnesium salt (1:3) (9CI) (CA INDEX NAME)
    NH<sub>2</sub>
H_2N-B-NH_2
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## **●**3 Mg

IT

RN

CN

ΙT

RN CN

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ΙT
    12057-71-5, Magnesium nitride
        (kinetics of c-BN formation due to structural
        transition in the system h-BN/Mg3N2
RN
     12057-71-5 HCA
    Magnesium nitride (Mg3N2) (CA INDEX NAME)
CN
    STRUCTURE DIAGRAM IS NOT AVAILABLE ***
***
    75-7 (Crystallography and Liquid Crystals)
CC
     cubic boron nitride structural
ST
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transition kinetics
     Physical process kinetics
IT
     Structural phase transition
        (kinetics of c-BN formation due to structural
        transition in the system h-BN/Mq3N2
ΙT
     10043-11-5, Boron nitride, properties
        (cubic; kinetics of c-BN formation
        due to structural transition in the system h-BN
        /Mg3N2)
     121768-76-1, Boron magnesium nitride (BMg3N3)
IT
        (formation during c-BN formation due to
        structural transition in the system h-BN/
       Mg3N2)
     12057-71-5, Magnesium nitride
ΙT
        (kinetics of c-BN formation due to structural
        transition in the system h-BN/Mg3N2
     ANSWER 5 OF 30 HCA COPYRIGHT 2009 ACS on STN
126:333418 Original Reference No. 126:64737a,64740a Magnesium boron
     nitride used in synthesis of CBN. Zhang, Xiangfa; Zhou,
     Wanli; Li, Zhenhe; Li, Gang (Zhengzhou Inst. Abrasives and Grinding,
     Ministry of Mechanical Eng., 450007, Peop. Rep. China).
                                                              Moliao Moju
     Yu Moxue (1), 2-4, 10 (Chinese) 1995. CODEN: MMYMF5.
     ISSN: 1001-442X. Publisher: Moliao Moju Yu Moxue Bianjibu.
     On the base of prepg. and analyzing the ambient atm. phase
AΒ
     of magnesium boron nitride, the transition of magnesium boron
     nitride from ambient atm. phase to high-pressure
     phase are investigated over the pressure and temp. ranges
     2.5-5.1 GPa and 400-1600°C, resp. The nucleation
     characteristics of cubic BN (CBN)
     crystals are studied using hexagonal BN as
     starting material and magnesium boron nitride as catalyst.
     71330-55-7P, Boron magnesium nitride b2mg3n4
IT
        (catalyst; prepn. and high-pressure phase
        transition of magnesium boron nitride and its use as a
        catalyst in the synthesis of cubic BN
RN
     71330-55-7
                HCA
     Boranamine, 1-imino-, magnesium salt (2:3) (9CI) (CA INDEX NAME)
CN
H_2N-B=NH
```

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10043-11-5P, Boron nitride (BN
     ), preparation
        (cubic; prepn. and high-pressure phase
        transition of magnesium boron nitride and its use as a
        catalyst in the synthesis of cubic BN
     10043-11-5 HCA
RN
     Boron nitride (BN) (CA INDEX NAME)
CN
B \equiv N
CC
     57-7 (Ceramics)
     Section cross-reference(s): 49
     magnesium boron nitride catalyst prepn property;
ST
     cubic boron nitride prepn nitride
     catalyst
     Crystal nucleation
ΙT
        (cubic boron nitride; prepn. and
        high-pressure phase transition of magnesium
        boron nitride and its use as a catalyst in the
        synthesis of cubic BN)
     Catalysts
IΤ
        (magnesium boron nitride; prepn. and high-pressure phase
        transition of magnesium boron nitride and its use as a
        catalyst in the synthesis of cubic BN
     71330-55-7P, Boron magnesium nitride b2mg3n4
ΙT
        (catalyst; prepn. and high-pressure phase
        transition of magnesium boron nitride and its use as a
        catalyst in the synthesis of cubic BN
     10043-11-5P, Boron nitride (BN
IT
     ), preparation
        (cubic; prepn. and high-pressure phase
        transition of magnesium boron nitride and its use as a
        catalyst in the synthesis of cubic BN
    ANSWER 6 OF 30 HCA COPYRIGHT 2009 ACS on STN
123:128037 Original Reference No. 123:22499a,22502a High pressure
     phase transformations of cubic boron
     nitride from amorphous boron nitride using magnesium boron nitride
     as the catalyst. Singh, B. P.; Nover, G.; Will, G.
     (National Physical Laboratory, New, DELHI-110012, India).
                                                                 Journal
     of Crystal Growth, 152(3), 143-9 (English) 1995. CODEN:
     JCRGAE. ISSN: 0022-0248. Publisher: Elsevier.
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Results are described of high pressure phase
AΒ
     transformations of amorphous B nitride (aBN) to
     cubic B nitride (cBN) using Mg B nitride (Mg3B2N4) as a
     catalyst-solvent. Amorphous B nitride undergoes various
     structural modifications under high pressures and high temps. giving
     hexagonal, cubic and wurtzitic phases of
     B nitride. The min. pressure at which aBN starts transforming into
     cBN is 25 kbar at 1800°. This is the lowest pressure for cBN
     formation employing the catalyst-solvent process and is
     reported here for the 1st time.
     71330-55-7, Magnesium boride nitride (Mg3B2N4)
ΙT
        (catalyst in phase transitions. of
        amorphous boron nitride)
RN
     71330-55-7 HCA
     Boranamine, 1-imino-, magnesium salt (2:3) (9CI) (CA INDEX NAME)
CN
H_2N-B=NH
●3/2 Mg
     10043-11-5, Boron nitride, processes
ΙT
        (high pressure phase transitions of amorphous
        boron nitride using magnesium boron nitride as catalyst
       .)
     10043-11-5 HCA ·
RN
CN
     Boron nitride (BN) (CA INDEX NAME)
B \equiv N
CC
     75-1 (Crystallography and Liquid Crystals)
     Section cross-reference(s): 67
     boron nitride amorphous phase transition
ST
     catalyst; crystn amorphous boron nitride catalyst
     Catalysts and Catalysis
IT
        (magnesium boride nitride in phase transitions
        of amorphous boron nitride)
ΙT
     71330-55-7, Magnesium boride nitride (Mg3B2N4)
        (catalyst in phase transitions. of
        amorphous boron nitride)
     10043-11-5, Boron nitride, processes
ΙT
        (high pressure phase transitions of amorphous
        boron nitride using magnesium boron nitride as catalyst
```

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ANSWER 7 OF 30 HCA COPYRIGHT 2009 ACS on STN
123:39192 Original Reference No. 123:7029a,7032a Rapid formation of
     cubic boron nitride in the system
     Mg3N2-hBN. Lorenz, H.; Orgzall, I.; Hinze, E.
     (Maerkische Fachhochschule, FB Physikalische Technik Frauenstuhlweg
     31, D-58644, Iserlohn, Germany). Diamond and Related Materials,
     4(8), 1050-5 (English) 1995. CODEN: DRMTE3.
                Publisher: Elsevier.
     0925-9635.
     The catalytic transformation from hexagonal (
AΒ
     h)-BN to cubic (c)-BN
     in the system Mg3N2-hBN was investigated under
     high pressures and temp. using in-situ sensing methods.
     threshold of the cBN formation region (approx. 1550 K at
     5.5 GPa), very fast formation processes leading to submicron
     cBN grains are obsd. in a small temp. interval (140 K at 5.5
            The transformation proceeds in a eutectic melt.
     assumptions of dissoln. and pptn. could be confirmed.
     intermediate phase formed under these thermodn. conditions
     is Mg3BN3 thus forming the solvent for this process.
     12057-71-5, Magnesium nitride Mg3N2
IT
        (catalyst/solvent; rapid formation of cubic
        boron nitride in the system Mg3N2-
        hexagonal BN by catalytic
        transformation)
     12057-71-5
                HCA
RN
     Magnesium nitride (Mg3N2)
                                (CA INDEX NAME)
CN
***
    STRUCTURE DIAGRAM IS NOT AVAILABLE ***
     10043-11-5, Boron nitride, processes
IT
        (cubic; rapid formation of cubic
        boron nitride in the system Mg3N2-
        hexagonal BN by catalytic
        transformation)
     10043-11-5
RN
                HCA
     Boron nitride (BN) (CA INDEX NAME)
CN
B \equiv N
CC
     57-2 (Ceramics)
ST
     boron nitride cubic phase
     formation; magnesium nitride system cubic boron
     nitride
     12057-71-5, Magnesium nitride Mg3N2
IT
        (catalyst/solvent; rapid formation of cubic
```

boron nitride in the system Mg3N2-

10043-11-5, Boron nitride, processes

hexagonal BN by catalytic

transformation)

IT

(cubic; rapid formation of cubic boron nitride in the system Mg3N2hexagonal BN by catalytic transformation)

L67 ANSWER 8 OF 30 HCA COPYRIGHT 2009 ACS on STN
122:15375 Original Reference No. 122:3101a,3104a High pressure

phase transformations in turbostratic boron

nitride using magnesium boron nitride as the catalyst.

Bindal, M. M.; Singh, B. P.; Singhal, S. K.; Nayar, R. K.; Chopra,

Rajeev (High Pressure Technology Division, National Physical

Laboratory, Dr. K.S. Krishnan Road, New, DELHI-110012, India).

Journal of Crystal Growth, 144(1/2), 97-102 (English) 1994

. CODEN: JCRGAE. ISSN: 0022-0248. Publisher: Elsevier.

Results of high pressure phase transformations AB in turbostratic boron nitride (tBN) using magnesium boron nitride as the catalyst-solvent are described. It was obsd. that turbostratic boron nitride undergoes various structural changes accompanied with the formation of hexagonal, cubic and wurtzitic modifications of boron nitride at high pressures and high temps. It was also found that the formation of these phases is sensitive to the pressures and temps. prevailing in the reaction zone. At higher pressure (>40 kbar) and temps. (>1300°C), cubic boron nitride (CBN) was obsd. as the predominant phase, whereas at lower pressure (≤40 kbar) and 1300°C, the predominant phase was that of wurtzitic boron nitride (WBN). The tBN - WBN phase transformation under static high P-T conditions with the use of catalyst-solvent process is reported for the first time.

IT 123213-37-6, Magnesium boride nitride
 (catalyst; high-pressure phase
 transformations in turbostratic boron nitride using
 magnesium boron nitride as catalyst)

RN 123213-37-6 HCA

CN Magnesium boride nitride (CA INDEX NAME)

Component	Ratio	Component
•	<u> </u>	Registry Number
========+	-======================================	-======================================
N	х	17778-88-0
В	x	. 7440-42-8
Mg	. x	7439-95-4

IT 10043-11-5, Boron nitride, processes
 (turbostratic; high-pressure phase
 transformations in turbostratic boron nitride using
 magnesium boron nitride as catalyst)

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10043-11-5 HCA
RN
     Boron nitride (BN) (CA INDEX NAME)
CN
B \equiv N
     57-2 (Ceramics)
CC
    phase transformation turbostratic boron nitride
ST
    pressure
    Phase transition
IT
        (high-pressure phase transformations in
        turbostratic boron nitride using magnesium boron nitride as
        catalyst)
     123213-37-6, Magnesium boride nitride
ΙT
        (catalyst; high-pressure phase
        transformations in turbostratic boron nitride using
       magnesium boron nitride as catalyst)
ΙT
     10043-11-5, Boron nitride, processes
        (turbostratic; high-pressure phase
        transformations in turbostratic boron nitride using
       magnesium boron nitride as catalyst)
L67 ANSWER 9 OF 30 HCA COPYRIGHT 2009 ACS on STN
121:115756 Original Reference No. 121:20789a,20792a Effect of magnesia
     on the formation of cubic boron nitride
       Xu, Xiaowei; Li, Yuping; Ma, Wenjun; Guo, Weili (Department
     Physical Chemistry, University Science Technology, Beijing, 100083,
     Peop. Rep. China). Rengong Jingti Xuebao, 23(2), 165-8 (English)
                           ISSN: 1000-9868.
     1994. CODEN: RJXUEN.
     The effect of MgO on the synthesis of cubic BN (
AΒ
     cBN) using Mg, Mg3N2, Mg3B2N4 as catalysts
     , was investigated by comparing the exptl. results of adding MgO to
     that of not adding MgO to the starting material. The results show
     that in some cases the synthesis of cBN is adversely
     affected, e.g., MgO formation in the growth front of cBN
     crystals hinders the diffusion of BN to the cBN crystal
     surfaces, and the MgO contained in the cBN crystals
     affects their transparency. However, the reaction of MgO with
     harmful B2O3 impurities are favorable for the synthesis of
     cBN.
     1309-48-4, Magnesia, properties
IT
        (effect of, on phase transition in
        cubic boron nitride manuf.)
RN
     1309-48-4 HCA
CN
     Magnesium oxide (MgO) (CA INDEX NAME)
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13703-83-8P, Magnesium borate (Mg2B2O5)
IT
        (formation of, in cubic boron nitride
       manuf., by reaction of magnesia with boron oxide impurities)
RN
     13703-83-8
                HCA
     Diboric acid, magnesium salt (1:2) (CA INDEX NAME)
CN
        OН
   OH
HO-B-O-B-OH
   ■2 Ma
     10043-11-5P, Boron nitride, preparation
ΙT
        (phase transition of, hexagonal-
        cubic, catalyst for, effect of magnesia on)
     10043-11-5 HCA
RN
     Boron nitride (BN) (CA INDEX NAME)
CN
B \equiv N
     7439-95-4, Magnesium, uses 12057-71-5, Magnesium
IT
     nitride 71330-55-7, Boron magnesium nitride (B2Mg3N4)
        (phase-transfer catalyst, effect of magnesia
        on, in cubic boron nitride manuf.)
     7439-95-4
               HCA
RN
CN
    Magnesium (CA INDEX NAME)
Mg
RN
     12057-71-5 HCA
    Magnesium nitride (Mg3N2) (CA INDEX NAME)
CN
***
    STRUCTURE DIAGRAM IS NOT AVAILABLE ***
RN
     71330-55-7 HCA
CN
     Boranamine, 1-imino-, magnesium salt (2:3) (9CI) (CA INDEX NAME)
H_2N-B=NH
```

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CC
     57-2 (Ceramics)
     magnesia cubic boron nitride
ST
     catalyst; magnesium boronitride catalyst
     Impurities and Impurity centers
IT
        (boron oxide, reaction of, with magnesia, for magnesium borate,
        in cubic boron nitride manuf.)
     Catalysts and Catalysis
IT
        (phase-transfer, magnesium and magnesium nitride and
        magnesium boronitride, effect of magnesia on, in cubic
        boron nitride manuf.)
     1309-48-4, Magnesia, properties
IT
        (effect of, on phase transition in
        cubic boron nitride manuf.)
     13703-83-8P, Magnesium borate (Mg2B2O5)
ΙT
        (formation of, in cubic boron nitride
        manuf., by reaction of magnesia with boron oxide impurities)
     1303-86-2, Boron oxide, reactions
IT
        (impurities, reaction of, with magnesia, for magnesium borate, in
        cubic boron nitride manuf.)
     10043-11-5P, Boron nitride, preparation
IT
        (phase transition of, hexagonal-
        cubic, catalyst for, effect of magnesia on)
     7439-95-4, Magnesium, uses 12057-71-5, Magnesium
IT
     nitride 71330-55-7, Boron magnesium nitride (B2Mg3N4)
        (phase-transfer catalyst, effect of magnesia
        on, in cubic boron nitride manuf.)
     ANSWER 10 OF 30 HCA COPYRIGHT 2009 ACS on STN
120:285863 Original Reference No. 120:50177a,50180a Method for
     preparing single crystals of cubic boron
     nitride. Bocquillon, Genevieve; Bogicevic, Christine;
     Loriers Susse, Christiane; Loriers, Jean (Centre National de la
     Recherche Scientifique, Fr.). Fr. Demande FR 2686101 A1
     19930716, 10 pp.
                       (French). CODEN: FRXXBL.
                                                  APPLICATION: FR
     1992-306 19920114.
     In the method, involving conversion of hexagonal
AΒ
     BN in the presence of a catalyst contg. at least
     an alkali metal or alk. earth nitride in a high-pressure high-temp.
     app., an element (Al, B, Si, Zr, or Ti) is added to the
     catalyst.
     12057-71-5, Magnesium nitride 26134-62-3, Lithium
IT
     nitride
        (catalyst, in prepg. single crystals of cubic
        boron nitride)
     12057-71-5 HCA
RN
     Magnesium nitride (Mg3N2)
CN
                                (CA INDEX NAME)
    STRUCTURE DIAGRAM IS NOT AVAILABLE ***
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26134-62-3 HCA

RN

```
CN Lithium nitride (Li3N) (CA INDEX NAME)

Li
Li-N-Li
```

IT 10043-11-5P, Boron nitride, preparation (cubic, prepn. of single crystals of)

RN 10043-11-5 HCA.

CN Boron nitride (BN) (CA INDEX NAME)

 $B \equiv N$ 

IC ICM C30B029-38 ICS C30B009-00; C01B021-064; B01J003-06

CC 75-1 (Crystallography and Liquid Crystals)
Section cross-reference(s): 49

ST **cubic boron nitride** single crystal prepn

Titanium, uses 7440-21-3, Silicon, uses 7440-32-6, Titanium, uses 7440-42-8, Boron, uses 7440-67-7, Zirconium, uses (catalyst additive, in prepg. single crystals of cubic boron nitride)

12013-82-0, Calcium nitride 12057-71-5, Magnesium nitride 26134-62-3, Lithium nitride (catalyst, in prepa. single crystals of cubic

(catalyst, in prepg. single crystals of cubic boron nitride)

IT 10043-11-5P, Boron nitride, preparation (cubic, prepn. of single crystals of)

RE

(1) Anon; US 4287164 A HCA

(2) Anon; US 4980730 A HCA

L67 ANSWER 11 OF 30 HCA COPYRIGHT 2009 ACS on STN

120:60846 Original Reference No. 120:10921a,10924a Molded materials for manufacture of cubic boron nitride sintered products. Shindo, Toshihiko; Murayama, Toshuki; Sato, Yutaka; Kashida, Shu (Shinetsu Chemical Industry Co., Ltd., Japan). Jpn. Kokai Tokkyo Koho JP 05246765 A 19930924 Heisei, 5 pp. (Japanese). CODEN: JKXXAF. APPLICATION: JP 1992-80403 19920302.

The materials are hexagonal BN of gas transmission 0.01-0.3 cm2/s that are impregnated with catalysts which convert hexagonal BN to cubic BN. The materials are useful for the manuf. of high-purity cubic BN at high yield.

```
12057-71-5, Magnesium nitride (mg3n2)
IT
        (catalyst, for conversion of hexagonal
        boron nitride to cubic boron
        nitride during sintering)
     12057-71-5 HCA
RN
     Magnesium nitride (Mg3N2) (CA INDEX NAME)
CN
    STRUCTURE DIAGRAM IS NOT AVAILABLE ***
ΙT
     10043-11-5P, Boron nitride, preparation
        (cubic, prepn. of, by conversion from hexagonal
        phase)
     10043-11-5 HCA
RN
     Boron nitride (BN) (CA INDEX NAME)
CN
B \equiv N
IC
     ICM C04B035-58
     ICS B01J003-06; B01J027-24; B01J035-10; B01J037-02; B28B003-00;
          C01B021-064
CC
     57-2 (Ceramics)
     cubic boron nitride ceramic;
ST
     hexagonal boron nitride conversion
     ceramic
     Ceramic materials and wares
IT
        (boron nitride, cubic, prepn. of)
     Catalysts and Catalysis
ΙT
        (for conversion of hexagonal boron
        nitride to cubic phase)
     12057-71-5, Magnesium nitride (mg3n2)
IT
        (catalyst, for conversion of hexagonal
        boron nitride to cubic boron
        nitride during sintering)
     71330-55-7
IT
        (ceramics, prepn. of for manuf. of high-purity cubic
        boron nitride products)
IT
     10043-11-5P, Boron nitride, preparation
        (cubic, prepn. of, by conversion from hexagonal
        phase)
     ANSWER 12 OF 30 HCA COPYRIGHT 2009 ACS on STN
118:257597 Original Reference No. 118:44734h,44735a
                                                      New concept of the
     synthesis of cubic boron nitride.
     Nakano, Satoshi; Fukunaga, Osamu (Dep. Inorg. Mater., Tokyo Inst.
     Technol., Tokyo, 152, Japan). Metals, Materials and Processes,
     3(4), 269-72 (English) 1992. CODEN: MEMPEX.
     0970-423X.
     Equil. phase boundary between hBN and
AB -
     cBN was detd. by the reactions from cBN to
```

ΙT

RN

CN

IT

RN

CN

CC

ST

IT

IT

AB

·IT

\*\*\*

```
hBN and from hBN to cBN. The boundary
     curve is expressed as P=T/200 - 3.5 (GPa. °C). Formation
     region of cBN in the BN-catalyst system showed
     distinct threshold pressure at about 5 GPa. The threshold pressure
     was found to decrease to about 3.8 GPa by the use of decompn.
     reaction of Mg3BN3.
     12057-71-5, Magnesium nitride (Mg3N2)
        (cubic boron nitride synthesis by
        decompn. of)
     12057-71-5 HCA
     Magnesium nitride (Mg3N2) (CA INDEX NAME)
    STRUCTURE DIAGRAM IS NOT AVAILABLE ***
     10043-11-5P, Boron nitride, preparation
        (cubic, synthesis of, phase boundary equil.
        between modifications in relation to)
     10043-11-5 HCA
     Boron nitride (BN) (CA INDEX NAME)
B \equiv N
     49-5 (Industrial Inorganic Chemicals)
     Section cross-reference(s): 57
     cubic boron nitride synthesis
     12057-71-5, Magnesium nitride (Mg3N2)
        (cubic boron nitride synthesis by
        decompn. of)
     10043-11-5P, Boron nitride, preparation
        (cubic, synthesis of, phase boundary equil.
        between modifications in relation to)
L67 ANSWER 13 OF 30 HCA COPYRIGHT 2009 ACS on STN
                                                      Manufacture of
115:186341 Original Reference No. 115:31801a,31804a
     finely divided cubic boron nitride
     from hexagonal boron nitride in the
     presence of phase-transformation
     catalysts. Lorenz, Helmar; Kuehne, Ulrich; Flegel, Karin;
     Hohlfeld, Christian; Lorenz, Bernd; Thaenert, Christian; Stromeyer,
     Regina (Akademie der Wissenschaften der DDR, Germany). Ger. (East)
     DD 291533 A5 19910704, 5 pp. (German). CODEN: GEXXA8.
     APPLICATION: DD 1990-337025 19900110.
     Using alk. earth metals or alk. earth nitrides or boronitrides, or
     their mixts., the phase transfer is carried out at 5.5-7.0
     GPa, 1250-1450°, for 10-90 s. The resulting cubic
     BN is suitable for use in the manuf. of abrasives.
     7439-95-4, Magnesium, uses and miscellaneous
     12057-71-5, Magnesium nitride (Mg3N2)
```

123213-37-6, Magnesium boride nitride

```
(catalyst, in cubic boron
nitride powder manuf. from hexagonal
boron nitride)
```

7439-95-4 HCA RN

Magnesium (CA INDEX NAME) CN

Mq

12057-71-5 HCA RN ·

Magnesium nitride (Mg3N2) (CA INDEX NAME)

\*\*\* STRUCTURE DIAGRAM IS NOT AVAILABLE \*\*\*

RN 123213-37-6 HCA

Magnesium boride nitride (CA INDEX NAME) CN

Component		Ratio	1	Component Registry Number
==========	==+====	=========	====+=	
N .	1 .	X		17778-88-0
В		X	1	7440-42-8
Mq	1	X	1	7439-95-4

- IC ICM C01B021-064
- 49-5 (Industrial Inorganic Chemicals) CC

Section cross-reference(s): 57

boron nitride hexagonal cubic ST

manuf

Alkaline earth metals IT

> (alk. earth metals and nitrides and boronitrides, in cubic boron nitride powder manuf.

from hexagonal boron nitride)

Alkaline earth compounds ΙT

(boride nitrides, alk. earth metals and nitrides and boronitrides, in cubic boron nitride powder manuf. from hexagonal boron nitride)

ITAlkaline earth pnictides

(nitrides, alk. earth metals and nitrides and boronitrides, in cubic boron nitride powder manuf.

from hexagonal boron nitride)

**7439-95-4**, Magnesium, uses and miscellaneous 7440-70-2, IT Calcium, uses and miscellaneous 12013-82-0, Calcium nitride 12057-71-5, Magnesium nitride (Mg3N2) 65453-51-2, Calcium boronitride (Ca3B2N4) 123213-37-6,

Magnesium boride nitride (catalyst, in cubic boron-

nitride powder manuf. from hexagonal

boron nitride)

```
ANSWER 14 OF 30 HCA COPYRIGHT 2009 ACS on STN
L67
115:82539 Original Reference No. 115:14038h,14039a Synthesis of
     cubic boron nitride using magnesium as
     the catalyst. Bindal, M. M.; Singhal, S. K.; Singh, B.
     P.; Nayar, R. K.; Chopra, R.; Dhar, A. (Natl. Phys. Lab., New Delhi,
     110012, India). Journal of Crystal Growth, 112(2-3), 386-401
     (English) 1991. CODEN: JCRGAE. ISSN: 0022-0248.
     Cubic BN single crystals were synthesized
AΒ
     employing the BN-Mg system under high pressure and high temp.
     conditions. During the exploration of the thermodynamically stable
     cubic BN growth region, apart from the
     cubic BN phase the other cryst.
     phases formed during the chem. reaction are MgO, Mg3(BO3)2,
     Mg3N2, MgB6, or MgB12. Along with these catalytic
     phases the wurtzitic BN was also detected and reported for
     the first time. The role of various phases formed during
     the reaction was examd. and a possible explanation for the formation
     of wurtzitic BN is suggested. The morphol. of cubic
     BN crystals and their yield were studied as a function of
     temp. and pressure. The effect of O impurity present in the
     starting hexagonal boron nitride on
     the conversion to cubic BN is also discussed.
     10043-11-5, Boron nitride (BN), properties
IT
        (crystal growth of cubic, under high pressure and high
        temp. using magnesium as catalyst)
RN
     10043-11-5 HCA
     Boron nitride (BN)
                         (CA INDEX NAME)
CN
B \equiv N
ΙT
     12057-71-5P, Magnesium nitride (Mg3N2)
        (formation of, in boron nitride-magnesium system)
     12057-71-5 HCA
RN
     Magnesium nitride (Mg3N2)
CN
                               (CA INDEX NAME)
***
    STRUCTURE DIAGRAM IS NOT AVAILABLE ***
     75-1 (Crystallography and Liquid Crystals)
CC
     Section cross-reference(s): 68
```

cubic; morphol boron nitride

boron nitride cubic crystal growth;
transition boron nitride hexagonal

ST

(of boron nitride cubic form, grown

```
under different pressure and temp. conditions)
     Crystal growth
IT
        (of boron nitride cubic form, under
        high pressure and high temp. using magnesium as catalyst
     7782-44-7, Oxygen, properties
IT
        (boron nitride hexagonal-
        cubic conversion in presence of impurity)
     7439-95-4, Magnesium, uses and miscellaneous
ΙT
        (catalyst, in crystal growth of cubic
       boron nitride)
     10043-11-5, Boron nitride (BN), properties
IT
        (crystal growth of cubic, under high pressure and high
        temp. using magnesium as catalyst)
     1309-48-4P, Magnesium oxide, preparation 12008-22-9P, Magnesium
ΙT
     boride (MgB6) 12057-71-5P, Magnesium nitride (
              12230-32-9P, Magnesium boride (MgB12)
     13767-68-5P, Magnesium borate (Mg3(BO3)2)
        (formation of, in boron nitride-magnesium system)
     ANSWER 15 OF 30 HCA COPYRIGHT 2009 ACS on STN
L67
114:67656 Original Reference No. 114:11493a,11496a On the choice of
     hexagonal boron nitride for
     high-pressure phase transformation using the
     catalyst solvent process. Bindal, M. M.; Singh, B. P.;
     Singhal, S. K.; Nayar, R. K.; Chopra, R.; Dhar, A. (Natl. Phys.
     Lab., New Delhi, 110 012, Ire.). Journal of Materials Science,
     26(1), 196-202 (English) 1991. CODEN: JMTSAS.
     0022-2461.
     The degree of 3-dimensional ordering, particle-size distribution,
AB
     and purity of 2 types of hexagonal BN were
     studied with a view to establish any possible correlation between
     these characteristics with the conversion of hexagonal
     form to cubic phase at high pressure and high
     temp. using Mg as the catalyst solvent. The cryst.
     phases formed at high pressure and high temp. were studied
     and the dependence of degree of graphitization of BN and purity on
     the cubic BN conversion discussed.
ΙT
     7439-95-4, Magnesium, uses and miscellaneous
        (catalyst solvent, boron nitride
        hexagonal-cubic phase
        transformation in presence of)
RN
     7439-95-4
               HCA
     Magnesium (CA INDEX NAME)
CN
```

```
10043-11-5, Boron nitride, properties
IT
        (hexagonal-cubic phase
        transformation of, by catalyst solvent process)
     10043-11-5 HCA
RN
     Boron nitride (BN) (CA INDEX NAME)
CN
B \equiv N
     57-2 (Ceramics)
CC
    boron nitride hexagonal cubic
ST
     transformation; catalyst solvent boron nitride
     transformation
     7439-95-4, Magnesium, uses and miscellaneous
IT
        (catalyst solvent, boron nitride
        hexagonal-cubic phase
        transformation in presence of)
     10043-11-5, Boron nitride, properties
IT
        (hexagonal-cubic phase
        transformation of, by catalyst solvent process)
     ANSWER 16 OF 30 HCA COPYRIGHT 2009 ACS on STN
                                                       Pecularities of the
112:144332 Original Reference No. 112:24285a,24288a
     cubic boron nitride formation in the
     system boron nitride-magnesium nitride (Mg3N2) [Erratum to
     document cited in CA111(20):179496b]. Hohlfeld, C. (Inst. High
     Pressure Res., Acad. Sci. GDR, Potsdam, 1561, Ger. Dem. Rep.).
     Journal of Materials Science Letters, 9(1), 111 (English)
     1990. CODEN: JMSLD5. ISSN: 0261-8028.
     Errors in the text and Table I have been cor.
                                                     The errors were not
AΒ
     reflected in the abstr. or the index entries.
     12057-71-5, Magnesium nitride (Mg3N2)
ΙT
        (catalyst, in hexagonal-to-cubic
        boron nitride phase
        transition (Erratum))
     12057-71-5 HCA
RN
     Magnesium nitride (Mg3N2) (CA INDEX NAME)
CN
*** STRUCTURE DIAGRAM IS NOT AVAILABLE ***
     10043-11-5P, Boron nitride (BN), preparation
IT
        (formation of cubic, mechanism of (Erratum))
     10043-11-5 HCA
RN
     Boron nitride (BN) (CA INDEX NAME)
CN
B \equiv N
CC
     57-2 (Ceramics)
```

Erratum cubic boron nitride formation

ST

```
model
    Ceramic materials and wares
ΙT
        (powd., boron nitride, formation of
        cubic, mechanism of (Erratum))
    12057-71-5, Magnesium nitride (Mg3N2)
ΙT
        (catalyst, in hexagonal-to-cubic
       boron nitride phase
        transition (Erratum))
    10043-11-5P, Boron nitride (BN), preparation
IT
        (formation of cubic, mechanism of (Erratum))
    ANSWER 17 OF 30 HCA COPYRIGHT 2009 ACS on STN
111:179496 Original Reference No. 111:29786h,29787a
                                                       Pecularities of the
    cubic boron nitride formation in the
    system boron nitride-magnesium nitride (Mg3N2). Hohlfeld,
    C. (Inst. High Pressure Res., Ger. Acad. Sci., Potsdam, 1561, Ger.
    Dem. Rep.). Journal of Materials Science Letters, 8(9), 1082-4
     (English) 1989. CODEN: JMSLD5. ISSN: 0261-8028.
    The formation mechanism of cubic (c) BN
AB
     from hexagonal (h) BN, particularly in
    the low-temp. region, was studied at varying temp. and 6.5 GPa by
     changing the stoichiometry of the starting Mg3N2 +
    h-BN powder mixt. in a belt-type pressure cell.
    After quenching, the products were examd. by x-ray diffraction and
     DTA. A distectic equil. model describing the rapid and massive
    c-BN formation is given.
    12057-71-5, Magnesium nitride (Mg3N2)
IT
        (catalyst, in hexagonal-to-cubic
       boron nitride phase
        transition)
RN
     12057-71-5 HCA
    Magnesium nitride (Mg3N2) (CA INDEX NAME)
CN
    STRUCTURE DIAGRAM IS NOT AVAILABLE ***
* * *
ΙT
     10043-11-5P, Boron nitride, preparation
        (formation of cubic, mechanism of)
RN
     10043-11-5 HCA
CN
     Boron nitride (BN) (CA INDEX NAME)
B \equiv N
     57-2 (Ceramics)
CC
ST
     cubic boron nitride formation model
     Ceramic materials and wares
IT
        (powd., boron nitride, formation of
        cubic, mechanism of)
```

12057-71-5, Magnesium nitride (Mg3N2)

(catalyst, in hexagonal-to-cubic

IT

# boron nitride phase transition)

IT 10043-11-5P, Boron nitride, preparation (formation of cubic, mechanism of)

L67 ANSWER 18 OF 30 HCA COPYRIGHT 2009 ACS on STN 111:15598 Original Reference No. 111:2661a,2664a Theory of

catalytic high-pressure phase transition

in boron nitride. Lorenz, Bernd; Lorenz, Helmar (Inst. High Pressure Res., Ger. Acad. Sci., Potsdam, DDR-1561, Ger. Dem. Rep.). Semiconductor Science and Technology, 4(4), 288-9 (English) 1989. CODEN: SSTEET. ISSN: 0268-1242.

AB The kinetics of the high-pressure **phase transition**in BN from the **hexagonal** to the **cubic phase** was investigated theor. On the basis of a nucleation and growth model various phys. quantities such as the net transformation rates at a fixed time were calcd. as functions of pressure and temp.

RN 12057-71-5 HCA

CN Magnesium nitride (Mg3N2) (CA INDEX NAME)

\*\*\* STRUCTURE DIAGRAM IS NOT AVAILABLE \*\*\*

IT 10043-11-5, Boron nitride, properties (phase transition in, theory of catalytic high-pressure)

RN 10043-11-5 HCA

CN Boron nitride (BN) (CA INDEX NAME)

#### $B \equiv N$

- CC 75-7 (Crystallography and Liquid Crystals) Section cross-reference(s): 67
- ST boron nitride **phase transition catalytic** theory
- IT Catalysts and Catalysis

(magnesium nitride, theory of high-pressure **phase** transition in boron nitride using)

IT 12057-71-5, Magnesium nitride (Mg3N2)

(catalysts, theory of high-pressure phase transition in boron nitride using)

IT 10043-11-5, Boron nitride, properties (phase transition in, theory of catalytic high-pressure)

L67 ANSWER 19 OF 30 HCA COPYRIGHT 2009 ACS on STN

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110:62445 Original Reference No. 110:10251a,10254a Synthesis of
     cubic boron nitride in the
    boron-nitrogen-magnesium ternary system. Vasilescu, A.; Benea, I.;
     Copaciu, V.; Calu, G.; Mitea, D. (Inst. Phys. Met. Technol.,
    Bucharest, Rom.). Sverkhtverdye Materialy (3), 23-5 (Russian)
     1988. CODEN: SVMAD2. ISSN: 0203-3119.
     The transformation of hexagonal BN (BNh) into
AB
     cubic BN (BNc) in the presence of Mg3N2,
    Mg, and MgB2 catalysts was studied. Tests were made with
     2 BNh specimens contg. 0.7 and 4% B2O3. The basic and impurity
    phases in BNc crystals were detd. by x-ray diffraction and
     the concn. of Mg by emission spectroscopy. The possible reactions
     in BN-catalyst-B2O3 systems were analyzed on the basis of
     exptl. data. A correlation was established between the impurity
     content in BNc and B2O3 content in the BNh.
     12057-71-5, Magnesium nitride (Mg3N2)
ΙT
        (catalyst, for cubic boron
       nitride formation from hexagonal phase
     12057-71-5 HCA
RN
     Magnesium nitride (Mg3N2)
                                (CA INDEX NAME)
CN
   STRUCTURE DIAGRAM IS NOT AVAILABLE ***
     10043-11-5P, Boron nitride, preparation
IT
        (cubic, formation of, from hexagonal
       boron nitride)
     10043-11-5 HCA
RN
     Boron nitride (BN) (CA INDEX NAME)
CN
B \equiv N
     57-7 (Ceramics)
CC
ST
     cubic boron nitride magnesium
     catalyst
     Catalysts and Catalysis
IT
        (for cubic boron nitride formation
        from hexagonal phase)
                                                    12007-25-9, Magnesium
     7439-95-4, Magnesium, uses and miscellaneous
IT
     diboride 12057-71-5, Magnesium nitride (Mg3N2)
        (catalyst, for cubic boron
       nitride formation from hexagonal phase
     10043-11-5P, Boron nitride, preparation
IT
        (cubic, formation of, from hexagonal
       boron nitride)
     ANSWER 20 OF 30 HCA COPYRIGHT 2009 ACS on STN
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102:189824 Original Reference No. 102:29725a,29728a Synthesis of

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cubic boron nitride. (Showa Denko K. K.,
     Japan). Jpn. Kokai Tokkyo Koho JP 59217608 A 19841207
     Showa, 3 pp. (Japanese). CODEN: JKXXAF. APPLICATION: JP
     1983-90602 19830525.
     Hexagonal BN is placed in a heat-resistant
AΒ
     vessel with C, heat-treated in N2 at 2000-2400°, then mixed
     with a cubic-BN forming catalyst, and
     treated under a pressure and a temp. which the cubic-
    BN is stable. The products are esp. useful for grinding
     stones and cutting tools. Thus, 8 hexagonal-BN
    blocks were placed in a C-crucible contg. 2 C blocks and heated for
     3 h at 2200° in a high-frequency induction furnace to give
     light yellow-colored hexagonal BN particles.
     The particles were buried in powd. Mg3N2, heated for 5 h
     at 1150° (to give hexagonal-BN contg.
     .apprx.2 wt.% Mg3N2B4), and press-sintered for 30 min at .apprx.50
     kbar and 1450° to give a cubic-BN block
     having Knoop hardness 5650 kg/mm2 and cubic-BN
     purity 99.9%.
ΙT
     10043-11-5P, preparation
        (synthesis of cubic, from hexagonal
        phase, for grinding stones and cutting tools)
RN.
     10043-11-5 HCA
     Boron nitride (BN) (CA INDEX NAME)
CN
B \equiv N
IC
     ICM C01B021-064
     ICS C04B035-58
CC
     57-7 (Ceramics)
     cubic boron nitride synthesis;
ST
     hexagonal boron nitride heat treatment;
     cutting tool cubic boron nitride
ΤТ
     Size reduction apparatus
        (grinding stones, boron nitride synthesis
        for, cubic-phase)
IT
        (cutting, boron nitride synthesis for,
        cubic-phase)
     96281-68-4P
ΙT
        (formation of, in hexagonal boron
        nitride, in synthesis of cubic phase)
IT
     10043-11-5P, preparation
        (synthesis of cubic, from hexagonal
        phase, for grinding stones and cutting tools)
```

ANSWER 21 OF 30 HCA COPYRIGHT 2009 ACS on STN

L67

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102:49948 Original Reference No. 102:7807a,7810a Production of
     cubic crystalline boron nitride.
     Kreubig, D.; Noll, G. (Kloeckner-Humboldt-Deutz A.-G., Oberursel,
     Fed. Rep. Ger.). Report, BMFT-FB-T-84-025; Order No. N84-25836, 47
    pp. Avail. NTIS From: Gov. Rep. Announce. Index (U. S.) 1984,
     84(20), 126 (German) 1984.
     An appropriate high pressure high temp. app. for the prodn. of
AB
     cubic BN from hexagonal BN was
     developed and built, and a synthesis process was devised and tested.
    Mg3N2, Li3N, Al, and Si were investigated as
     initiators (catalysts) of the process. A first survey of
     the effect of the materials used and the synthesis parameters on the
     formation and growth of the cubic BN crystals
     was gained. Present work is concd. on the prodn. of cubic
     BN grains with properties as required by manufacturers of
     grinding and cutting tools.
     12057-71-5 26134-62-3
IT
        (catalyst, in cubic boron
        nitride manuf.)
     12057-71-5 HCA
RN
     Magnesium nitride (Mg3N2) (CA INDEX NAME)
CN
   STRUCTURE DIAGRAM IS NOT AVAILABLE ***
     26134-62-3 HCA
RN
     Lithium nitride (Li3N) (CA INDEX NAME)
CN
   Li
Li-N-Li
     10043-11-5P, preparation
ΙT
        (manuf. of cubic, for grinding and cutting)
RN
     10043-11-5 HCA
     Boron nitride (BN) (CA INDEX NAME)
CN
B \equiv N
CC
     57-7 (Ceramics)
ST
     cubic boron nitride manuf
     7429-90-5, uses and miscellaneous 7440-21-3, uses and
IT
     miscellaneous 12057-71-5 26134-62-3
        (catalyst, in cubic boron
        nitride manuf.).
     10043-11-5P, preparation
ΙT
        (manuf. of cubic, for grinding and cutting)
     ANSWER 22 OF 30 HCA COPYRIGHT 2009 ACS on STN
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L67

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101:215479 Original Reference No. 101:32611a,32614a Hard abrasive
     particles. (Sumitomo Electric Industries, Ltd., Japan).
     Tokkyo Koho JP 59121167 A 19840713 Showa, 4 pp.
     (Japanese). CODEN: JKXXAF. APPLICATION: JP 1982-234742 19821227.
     Polycryst. hard abrasive particles are composed of cubic
AΒ
     BN primary particles of av. particle size \geq 1\mu and
     1-5 vol.% cubic BN synthesizing catalyst
        The particles are manufd. by hot pressing a mixt. of 90-99.9
     vol.% hexagonal BN and 0.1-10 vol.% nitrides or
     boronitrides of a group IA or group IIA metal (as synthesizing
     catalyst) at 40-65 kbar and 1350-1800° (cubic
     BN is thermodynamically stable at this pressure and temp.
     range) to convert hexagonal BN into
     cubic BN and simultaneously converting it to a
     polycryst. body contg. solvents and then pulverizing to the desired
     particle size. The particles have high hardness and are useful for
     abrasion and grinding. Thus, hexagonal BN
     powder and Mg3N2 powder were treated in N atm. to give
     Mg3B2N4 powder. Hexagonal BN powder 97 vol.%
     and Mg3B2N4 powder 3 vol.% were mixed, molded, and treated at 50
     kbar and 1450° to give a body contg. 0.3 wt.% Mg. An x-ray
     diffractometer showed only the cubic BN
     diffraction peak. Then, the body was pulverized, plated with Ni,
     and processed to a grinding stone using 60/80 mesh particles and a
     resin binder. The grinding stone had a large grinding ratio.
     26134-62-3
IT
        (catalysts, for boron nitride
        hexagonal-to-cubic transformation for
        abrasives)
     26134-62-3 HCA
RN
     Lithium nitride (Li3N) (CA INDEX NAME)
CN
   Li
Li-N-Li
IT
     10043-11-5P, preparation
        (prepn. of cubic, with catalysts for
        transformation of hexagonal form, for abrasives)
RN
     10043-11-5
                HCA
CN
     Boron nitride (BN) (CA INDEX NAME)
B \equiv N
```

C04B035-58

57-7 (Ceramics)

IC.

CC

- ST grinding cubic boron nitride; abrasive boron nitride; group IIA nitride grinder; polycryst cubic boron nitride grinder
- IT Abrasives

(boron nitride prepn. for, with catalyst for hexagonal-to-cubic transformation)

IT Abrasives

> (grindstones, boron nitride prepn. for, with catalyst for hexagonal-to-cubic transformation)

12408-97-8 **26134-62-3** 53322-25-1 ΤТ 12013-82-0

71330-55-7 65453-51-2 65453-44-3

(catalysts, for boron nitride hexagonal-to-cubic transformation for abrasives)

**10043-11-5P**, preparation IT

> (prepn. of cubic, with catalysts for transformation of hexagonal form, for abrasives)

- ANSWER 23 OF 30 HCA COPYRIGHT 2009 ACS on STN 101:176353 Original Reference No. 101:26613a,26616a Sinters for high-hardness tools. (Sumitomo Electric Industries, Ltd., Japan). Jpn. Kokai Tokkyo Koho JP 59088375 A 19840522 Showa, 5 (Japanese). CODEN: JKXXAF. APPLICATION: JP 1982-197086 pp. 19821109.
- Cubic BN sinters for high-hardness tools are AΒ comprised of 10-85 vol.% Al203 which is homogeneously dispersed in a continuous phase of cubic BN (the balance) that is converted from hexagonal BN by Ca boride-nitride and/or Mg boride-nitride catalyst added as 0.01-5 wt.% of a Ca-B-N and/or Mg-B-N compd. The prepn. of the sinter is also claimed. The cubic BN sinter has excellent chem. stability, thermal resistance, and high hardness. Thus, a mixt. of hexagonal BN 50 and Al2O3 50 vol.% with Mg boride-nitride (3 wt.% of the hexagonal BN) was pressed and heated to give a sinter which was prepd. as a cutting tool that had excellent cutting properties.

71330-55-7 ΙT

> (catalyst, for boron nitride hexagonal to cubic phase transformation for ceramic cutting tools)

RN 71330-55-7 HCA

Boranamine, 1-imino-, magnesium salt (2:3) (9CI) (CA INDEX NAME) CN

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H_2N-B=NH
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## ●3/2 Mg

RN 10043-11-5 HCA

CN Boron nitride (BN) (CA INDEX NAME)

### $B \equiv N$

IC C04B035-58; C04B035-10; C22C029-00

CC 57-7 (Ceramics)

IT Catalysts and Catalysis

(alk. earth boride nitride, for **boron nitride hexagonal** to **cubic** transformation for ceramic cutting tools)

IT Ceramic materials and wares

(boron nitride, cubic, with alumina dispersed phase, for cutting tools)

IT Tools

(cutting, ceramic, cubic boron nitride, with alumina dispersed phase)

IT 65453-51-2 **71330-55-7** 

(catalyst, for boron nitride
hexagonal to cubic phase
transformation for ceramic cutting tools)

L67 ANSWER 24 OF 30 HCA COPYRIGHT 2009 ACS on STN

101:96505 Original Reference No. 101:14707a,14710a Cubic boron nitride. (Showa Denko K. K., Japan). Jpn. Kokai Tokkyo Koho JP 59073410 A 19840425 Showa, 5 pp. (Japanese). CODEN: JKXXAF. APPLICATION: JP 1982-180006 19821015.

AB A 2:(1-1.4) mol ratio mixt. of BN and nitrides of Be, Mg, Ca, Sr, and/or Ba is fired in an inert gas at 800-1300° and used as a catalyst for synthesis of cubic BN from

hexagonal BN. Thus, a mixt. of Mg3N2

0.8, Ca3N2 0.4, and BN 2 mol was fired in N gas at 1000° for 40 min, crushed to <150 mesh, mixed with hexagonal

BN at a 1:10 wt. ratio, compacted, and hot-pressed at 1500° and 58 kbar to give a cubic BN cylinder having crushing strength 4.11 + 108 kg/m2 (sic), compared to 3.61 when the catalyst mix was not prefired. The yield for both cases was 35 and 29%, resp. 12057-71-5 (catalysts, for transformation of hexagonal boron nitride to cubic phase cylinders) 12057-71-5 HCA Magnesium nitride (Mg3N2) (CA INDEX NAME) STRUCTURE DIAGRAM IS NOT AVAILABLE \*\*\* 10043-11-5, uses and miscellaneous (transformation of hexagonal, to cubic phase cylinders, nitride catalysts for) 10043-11-5 HCA Boron nitride (BN) (CA INDEX NAME)  $B \equiv N$ C01B021-064; B01J027-24 57-2 (Ceramics) nitride catalyst boron nitride transformation Ceramic materials and wares (boron nitride, cubic phase , cylinders of, from hexagonal boron nitride) Catalysts and Catalysis (nitride, for hexagonal boron nitride transformation to cubic phase cylinders) 12013-82-0 **12057-71-5** (catalysts, for transformation of hexagonal boron nitride to cubic phase cylinders) 10043-11-5, uses and miscellaneous (transformation of hexagonal, to cubic phase cylinders, nitride catalysts for) ANSWER 25 OF 30 HCA COPYRIGHT 2009 ACS on STN 99:42532 Original Reference No. 99:6621a,6624a Synthesis of cubic boron nitride. (Komatsu, Ltd., Japan). Jpn. Kokai Tokkyo Koho JP 58060604 A 19830411 (Japanese). CODEN: JKXXAF. APPLICATION: JP Showa, 3 pp. 1981-154775 19811001. Hexagonal BN contg. <3500 ppm 02 (preferably

<1000 ppm 02) is used for the synthesis of cubic

ΙT

RN

CN

ΤT

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ST

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ΙT

ΙT

AΒ

BN at >40,000 atm and  $>1200^{\circ}$  in the presence of, e.g. Si-Al, Si-AlN, Li, Mg, Ca, Li3N, Mg3N2, or Ca3N2 as catalyst. It can be used for making cutting tools for steels. Thus, hexagonal BN contg. 820 ppm 02 (100 parts) was mixed with powd. Si (20 parts) and AlN (5 parts), formed, and heated at 56,000 atm and 1650° for 20 min. The yield of cubic BN was 72%. **10043-11-5P**, preparation (synthesis of cubic, from hexagonal phase) 10043-11-5 HCA Boron nitride (BN) (CA INDEX NAME)  $B \equiv N$ C01B021-064; B01J027-24 57-7 (Ceramics) Section cross-reference(s): 55 cubic boron nitride synthesis Tools (cutting, cubic boron nitride synthesis for) 24304-00-5 7440-21-3, uses and miscellaneous (catalyst, in cubic boron nitride synthesis) **10043-11-5P**, preparation (synthesis of cubic, from hexagonal phase) ANSWER 26 OF 30 HCA COPYRIGHT 2009 ACS on STN 85:9601 Original Reference No. 85:1517a,1520a Phase transformation of wurtzite-type boron nitride at high temperatures and pressures. Hiraoka, Hideo; Fukunaga, Osamu; Iwata, Minoru (Cent. Res. Lab., Denki Kagaku Kogyo Co., Ltd., Tokyo, Japan). Yogyo Kyokaishi, 84(4), 163-70 (Japanese) 1976. CODEN: YGKSA4. ISSN: 0009-0255. Wurtzite-type BN powders produced by a shock compression method were treated at 1 atm to 80 kbar and at 650-2220 for 30 min. Phases were identified by x-ray diffraction and scanning electron microscopy. Direct transformation from wurtzite-type to cubic BN was obsd. at a lower pressure region than that of direct transformation from hexagonal to cubic BN. The P-T region of cubic BN formation was detd. This formation region of cubic BN disagreed with the stable region of

cubic BN owing to the sluggish rate of

transformation from wurtzite-type to cubic BN.

Mg3N2 catalyst accelerates the transformation. Tentative boundary among wurtzite-type, hexagonal, and cubic BN was discussed. IT 10043-11-5 (phase transformation of wurtzite-type, at high temp. and pressure) RN 10043-11-5 HCA Boron nitride (BN) (CA INDEX NAME) CN  $B \equiv N$ 57-7 (Ceramics) CC Section cross-reference(s): 68 boron nitride phase transformation ST10043-11-5 IΤ (phase transformation of wurtzite-type, at high temp. and pressure) ANSWER 27 OF 30 HCA COPYRIGHT 2009 ACS on STN 83:125343 Original Reference No. 83:19617a,19620a Synthesis of cubic boron nitride by the catalytic process. Fukunaga, Osamu; Sato, Tadao; Iwata, Minoru; Hiraoka, Hideo (Natl. Inst. Res. Inorg. Mater., Sakura, Proc. Int. Conf. High Pressure, 4th, Meeting Date 1974, 454-9. Editor(s): Osugi, Jiro. Phys.-Chem. Soc. Jpn.: Kyoto, Japan. (English) 1975. CODEN: 30RHAF. Growth pressure-temp. (P-T) regions of cubic BN AΒ in the systems, BN-Mg, BN-Li3N and BN-Mg3N2, were redetd. up to 80 kb. Hexagonal BN of different grades were used as starting materials. The habit, size and yield of cubic BN crystals were greatly The effect affected by the amt. of oxide in the starting materials. of oxide impurity on the P-T region of cubic BN, however, was not obvious. The P-T region of cubic BN in the present systems was basically consistent with the previous data. Superpressure was needed to form cubic BN below 1550° in these systems. The superpressure was discussed in relation to the breakage of sp2-type B-N linkage. The superpressure increased with decreasing temp. following an approx. linear relation. IT 10043-11-5

10043-11-5

RN

CN

(cubic, growth of, catalytic)

(CA INDEX NAME)

HCA

Boron nitride (BN)

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IT
    12057-71-5 26134-62-3
        (system, boron nitride-, cubic
       boron nitride formation in)
     12057-71-5 HCA
RN
    Magnesium nitride (Mg3N2) (CA INDEX NAME)
CN
*** STRUCTURE DIAGRAM IS NOT AVAILABLE ***
     26134-62-3 HCA
RN
    Lithium nitride (Li3N) (CA INDEX NAME)
CN
   Li
Li-N-Li
     78-5 (Inorganic Chemicals and Reactions)
CC
ST
    boron nitride cubic catalytic
ΙT
     10043-11-5
        (cubic, growth of, catalytic)
IT
     7439-95-4, properties
        (system, boron nitride-, cubic
       boron nitride formation in)
     12057-71-5 26134-62-3
ΙT
        (system, boron nitride-, cubic
       boron nitride formation in)
     ANSWER 28 OF 30 HCA COPYRIGHT 2009 ACS on STN
69:39313 Original Reference No. 69:7371a,7374a Mechanism of formation
     of cubic boron nitride. Filonenko, N.
     E.; Ivanov, V. I.; Sokhor, M. I.; Fel'dgun, L. I. Trudy -
     Vsesoyuznyi Nauchno-Issledovatel'skii Institut Abrazivov i
     Shlifovaniya, No. 2, 5-11 From: Ref. Zh., Khim. 1967, Abstr. No.
     15M23 (Russian) 1966. CODEN: TVNABG. ISSN: 0372-2945.
     The phys.-chem. conditions of formation of cubic B
AΒ
     nitride were studied. Some compns. in the ternary system
     Mg-B-N were examd. The products obtained were studied by
     microscopic, chem., and x-ray methods. A combined phase
     anal. with chem. treatment and sepn. in heavy liqs. was also carried
     out. At 38-40 kilobars and 1100-450°K. the reaction between
     Mg3N2 and elemental B will yield MgB2, MgB6, and
     hexagonal BN. At higher pressure (65 kilobars)
     and temp. (1860-2000°K.) the reaction products contain
     cubic BN as small (\leq 20 \, \mu), dark
     tetrahedral crystals in addn. to hexagonal BN.
     Cubic BN, obtained from a mixt. of
     hexagonal BN with metals at high pressures and
     temp., is formed according to the general principles of crystn. in
     ternary and more complex systems. When the mixt. consists of
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hexagonal BN and Mg the latter does not act as a catalyst but reacts with BN at  $1000^{\circ}$  to form Mg nitride and diboride according to 4Mg + 2BN = MgB2 + Mg3N2. To obtain any considerable amt. of cubic BN as crystals of several tenths of a  $\mu$  in size, the compn. of the reaction mixt. should be such that at the appropriate pressure and temp. the cubic BN becomes the 1st crystn. phase; i.e., a melt is obtained whose compn. is within the stability field of BN in the selected ternary or more complex system.  $10043-11-5 \qquad \text{(crystal growth of cubic)}$   $10043-11-5 \qquad \text{HCA}$  Boron nitride (BN) (CA INDEX NAME)

 $B \equiv N$ 

ŤТ

RN

CN

CC 70 (Crystallization and Crystal Structure)
ST cubic B nitride; nitride
B cubic; boron nitride

cubic; formation cubic B nitride

IT Crystal growth

(of boron nitride (BN) of cubic modification)

IT 10043-11-5

(crystal growth of cubic)

L67 ANSWER 29 OF 30 HCA COPYRIGHT 2009 ACS on STN 54:134225 Original Reference No. 54:25675f-i Abrasive boron nitride. Wentorf, Robert H., Jr. (General Electric Co.). US 2947617 19600802 (Unavailable). APPLICATION: US .

Cubic BN is prepd. having a hardness AΒ substantially equal to diamonds, while exhibiting thermal stability superior to presently available abrasive materials. Ordinary BN is subjected to an elevated temp. and pressure in the presence of at least 1 catalyst, e.g. an alkali, or alk. earth metal, Sn, Pb, Sb, or their nitrides. Thus, 3 parts by vol. of hexagonal BN and 1 part of lumps of Mg were subjected to 69,000-95,000 atm. at 1300-2100° for 3 min. av. yield of cubic BN was about 1/5 carat in the form of generally cylindrical jagged crystals with an av. diam. of Spectrog. examn. of the material formed at 86,000 atm. showed the presence of B and Mg. In scratch tests, this material scratched polished B carbide as well as the cubic and octahedral face of a diamond. The x-ray diffraction anal. indicated a cubic structure analogous to sphalerite with a unit-cell edge length of 3.615 A.  $\pm$  0.001A. at 25°. The material

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had a d. of 3.45. In other examples, Na, K, Li, Ba, Sr, Ca, Pb, Sb,
     Sn, Mg nitride, Li nitride, Ca nitride, mixts. of Ca and Li
    nitrides, Ca nitride and Na, Mg nitride and Mg, Mg nitride and Sn
    were used as catalysts. In other examples, the reaction
    mixt. was B and Ca with alternate layers of CaCN2 and powd. B, and a
    mixt. of Ni and Mg nitrides. Abrasive articles are prepd. by
    bonding cubic BN to a base member by any
     suitable means.
    12057-71-5P, Magnesium nitride
ΙT
        (as catalyst in BN manuf.)
     12057-71-5 HCA
RN
    Magnesium nitride (Mg3N2) (CA INDEX NAME)
CN
    STRUCTURE DIAGRAM IS NOT AVAILABLE ***
     26134-62-3P, Lithium nitride
        (as catalysts in BN manuf.)
     26134-62-3 HCA
RN
    Lithium nitride (Li3N) (CA INDEX NAME)
   Li
Li-N-Li
     10043-11-5P, Boron nitride, BN
TΤ
        (manuf. of cubic, at high pressure and temp. with
        catalyst, for abrasives)
     10043-11-5 HCA
RN
     Boron nitride (BN) (CA INDEX NAME)
CN
B \equiv N
     19 (Glass, Clay Products, Refractories, and Enameled Metals)
CC
     Alkali metal nitrides
IT
     Alkaline earth nitrides
     Nitrides
        (as catalysts in BN manuf.)
     Abrasives
IT
        (boron nitride (cubic) for)
IT
     Alkali metals
     Alkaline earth metals
        (catalysts, in BN manuf.)
IT
     Catalysts
        (for boron nitride (cubic) manuf.)
     12057-71-5P, Magnesium nitride 52036-89-2P, Lead nitride
IT
     55574-97-5P, Tin nitride
        (as catalyst in BN manuf.)
     12013-82-0P, Calcium nitride 26134-62-3P, Lithium nitride
IT
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143499-07-4P, Antimony nitride (as catalysts in BN manuf.)
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IT 7440-24-6P, Strontium

(catalysts in BN manuf.)

TT 7439-93-2P, Lithium 7439-95-4P, Magnesium 7440-31-5P, Tin 7440-36-0P, Antimony 7440-39-3P, Barium 7440-70-2P, Calcium 12136-83-3P, Sodium nitride

(catalysts, in BN manuf.)

IT 7439-92-1P, Lead

(catalysts, in BN transformation from hexagonal to cubic structure)

IT 10043-11-5P, Boron nitride, BN

(manuf. of cubic, at high pressure and temp. with catalyst, for abrasives)

L67 ANSWER 30 OF 30 HCA COPYRIGHT 2009 ACS on STN 51:96860 Original Reference No. 51:17447f-g Infrared spectra of inorganic solids. II. Oxides, nitrides, carbides, and borides. Brame, Edward G., Jr.; Margrave, John L.; Meloche, Villiers W. (Univ. of Wisconsin, Madison). Journal of Inorganic and Nuclear Chemistry, 5, 48-52 (Unavailable) 1957. CODEN: JINCAO. ISSN: 0022-1902.

AB cf. C.A. 51, 9318d. Infrared spectra from 2 to 16 μ were detd. for hexagonal Li3N, cubic Cu3N, hexagonal BN and AlN, cubic Mg3N2 and Zn3N2, hexagonal B2O3, rhombohedral Cr2O3, Ga2O3, Al2O3, and B4C, hexagonal SiC, tetragonal Mo2B, and undesignated CrN, ZrB2, and TiB2 phases. Of the

Mo2B, and undesignated CrN, ZrB2, and TiB2 **phases**. Of the four latter, only Mo2B showed any bands. Mass effect on major band position and familial spectral spectral character were discussed.

IT 10043-11-5, Boron nitride, BN 12057-71-5, Magnesium nitride, Mg3N2 26134-62-3, Lithium nitride

(spectrum of)

RN 10043-11-5 HCA

CN Boron nitride (BN) (CA INDEX NAME)

#### $B \equiv N$

RN 12057-71-5 HCA

CN Magnesium nitride (Mg3N2) (CA INDEX NAME)

\*\*\* STRUCTURE DIAGRAM IS NOT AVAILABLE \*\*\*

RN 26134-62-3 HCA

CN Lithium nitride (Li3N) (CA INDEX NAME)

Li | Li-N-Li

CC 3 (Electronic Phenomena and Spectra)

1T 409-21-2, Silicon carbide 1303-86-2, Boron oxide, B2O3
1308-38-9, Chromium oxide, Cr2O3 1308-80-1, Copper nitride (Cu3N)
1313-49-1, Zinc nitride, Zn3N2 1344-28-1, Aluminum oxide
10043-11-5, Boron nitride, BN 12024-21-4, Gallium oxide,
Ga2O3 12045-63-5, Titanium boride, TiB2 12045-64-6, Zirconium
boride, ZrB2 12057-71-5, Magnesium nitride, Mg3N2
12069-32-8, Boron carbide, B4C 24094-93-7, Chromium nitride, CrN
24304-00-5, Aluminum nitride, AlN 26134-62-3, Lithium
nitride
(spectrum of)